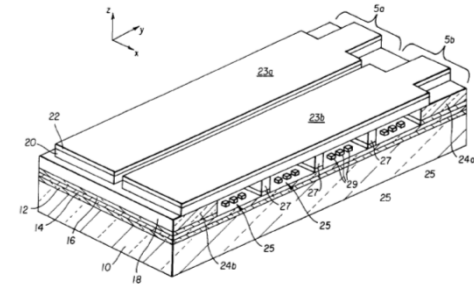


Grating Electromechanical Systems (GEMS), Laser Displays, and Related Doodles

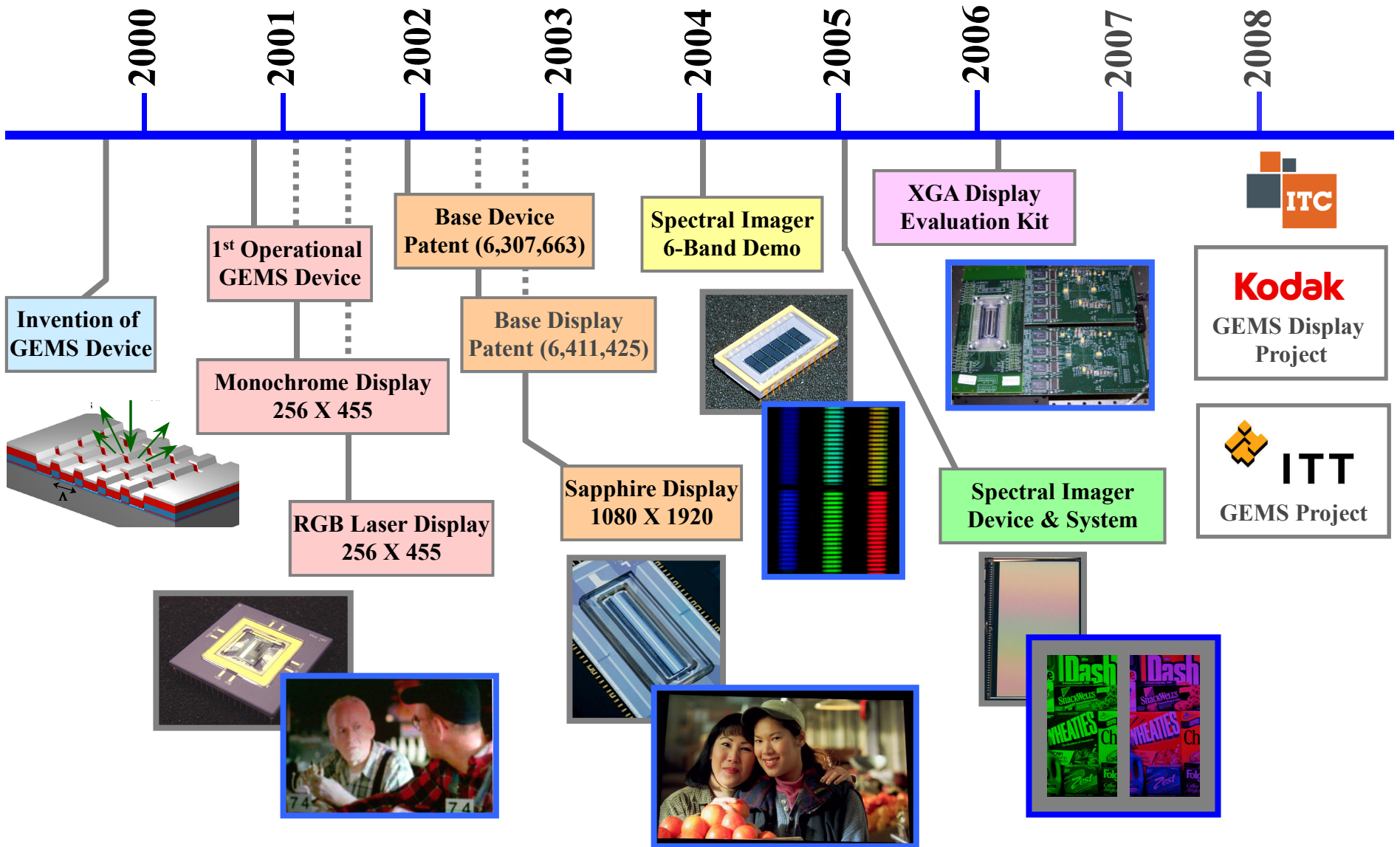


Marek W. Kowarz*
Infotonics Technology Center

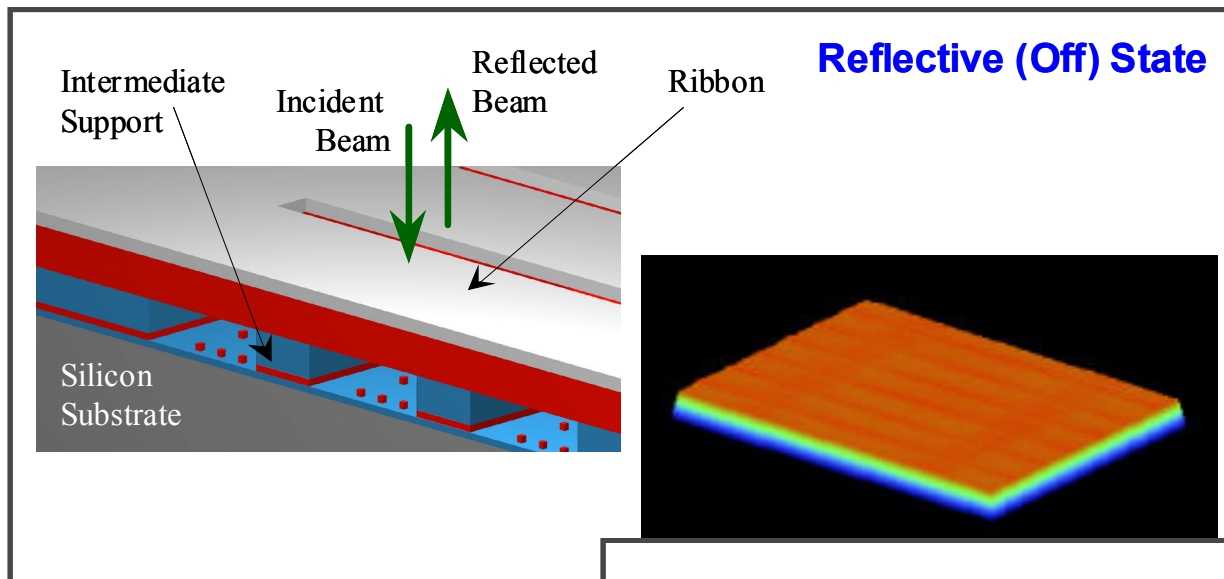
** Major portions of this work were performed when the
author was with Eastman Kodak Company.*

GEMS Technology: Timeline and Milestones

Grating ElectroMechanical System



GEMS Device



Typical Dimensions

Grating period = 15 to 50 μm

Actuation depth = 150 to 200 nm

Device Features

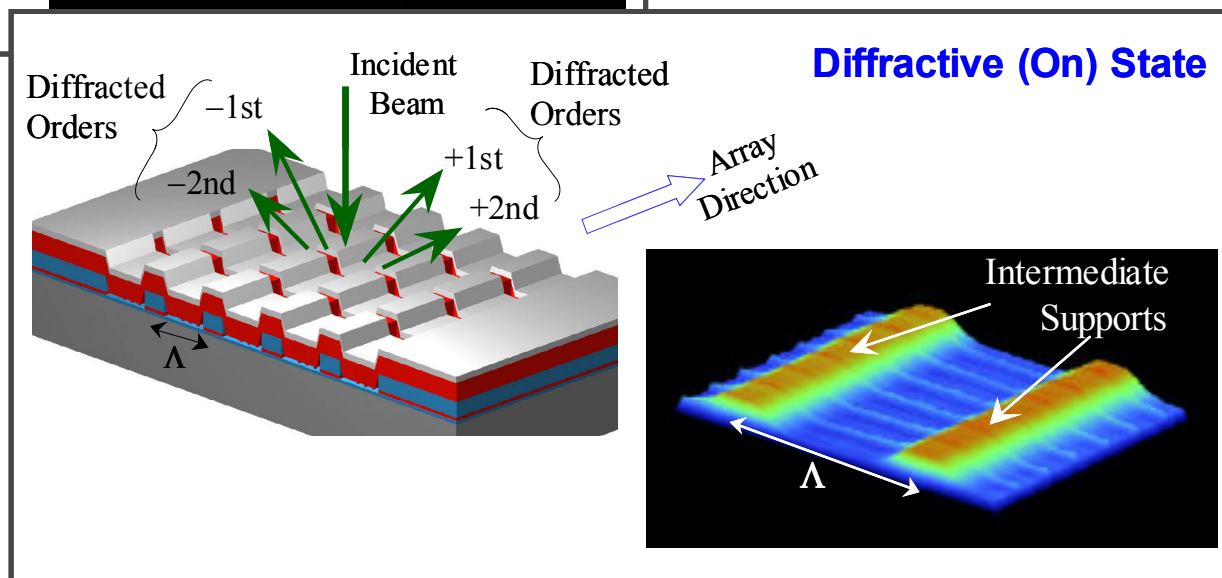
Very wide active area

\perp grating (Λ) direction

Digital operation

>2000:1 contrast

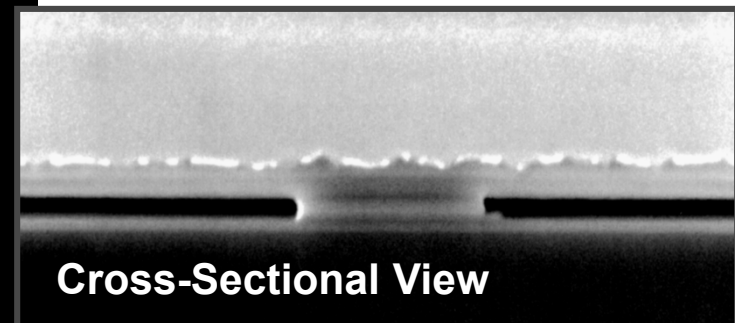
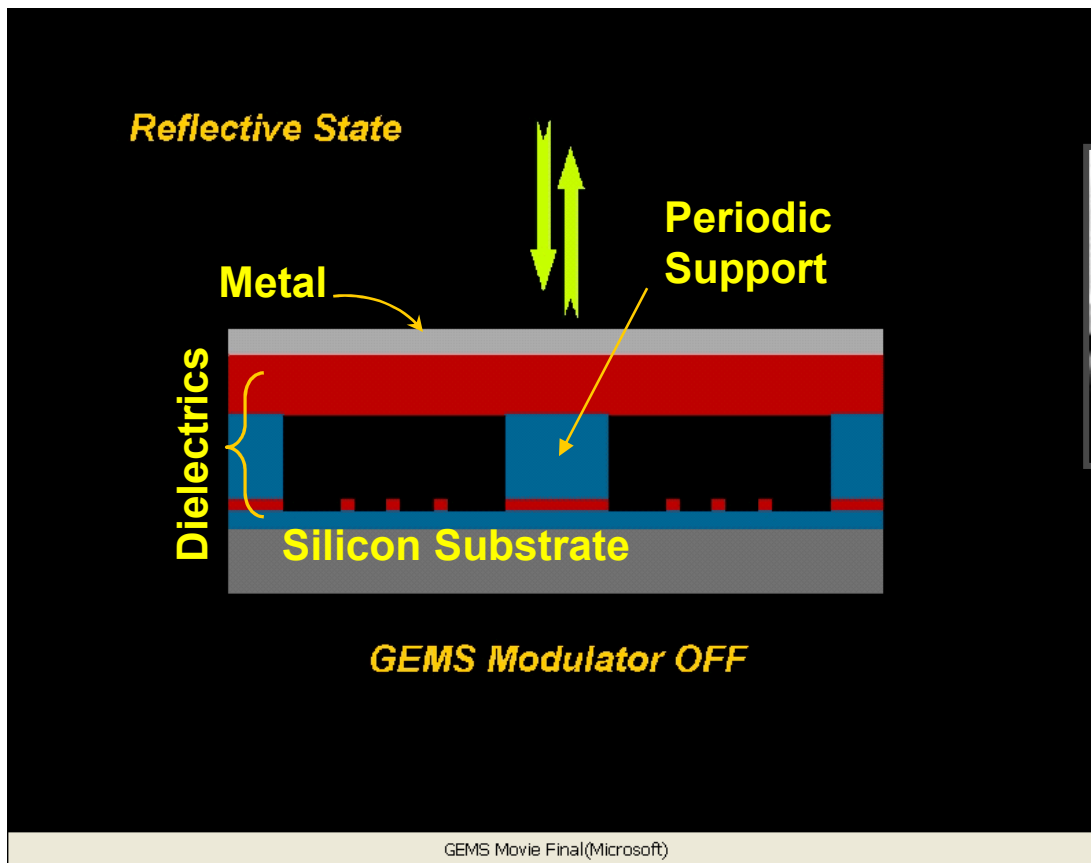
>60% multiorder efficiency



GEMS Device Structure and Operation

Grating ElectroMechanical System

The GEMS device consists of a linear array of pixels with electromechanical ribbons suspended above a hidden grating



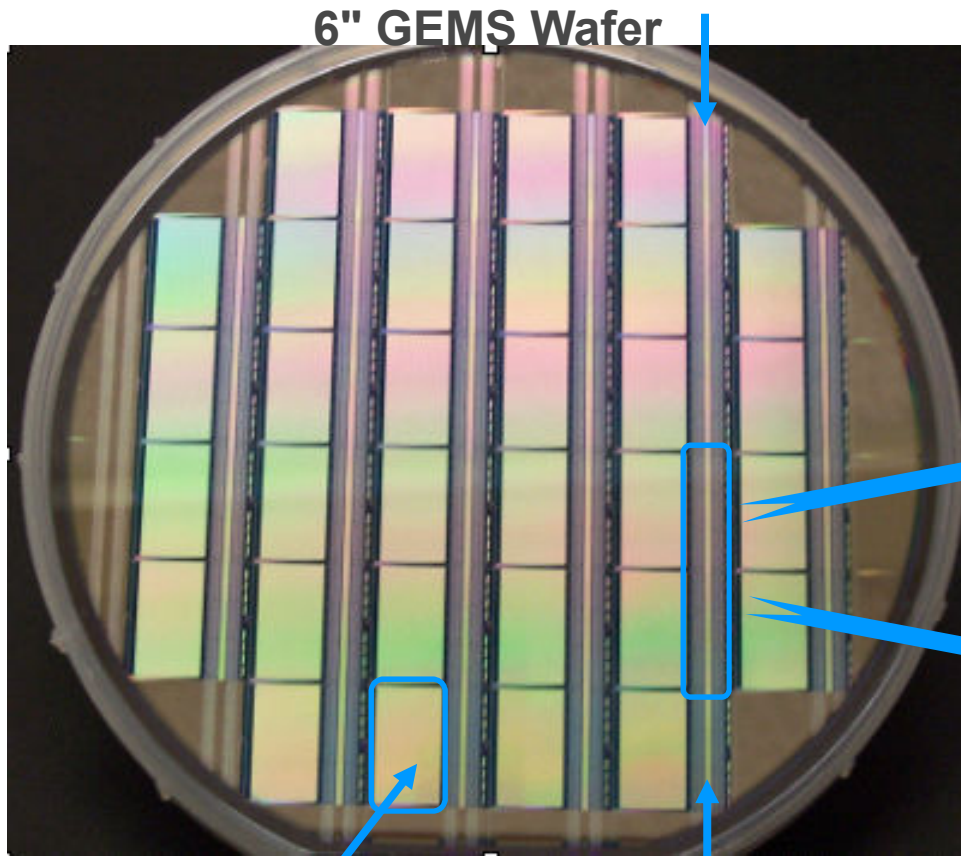
Typically

Pitch = 15 to 50 μm

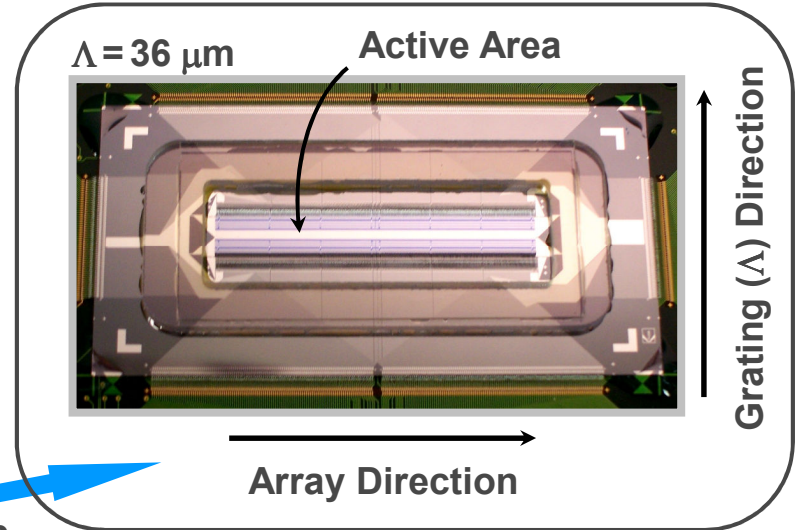
Actuation Depth = 150 to 200 nm

GEMS Device Wafer

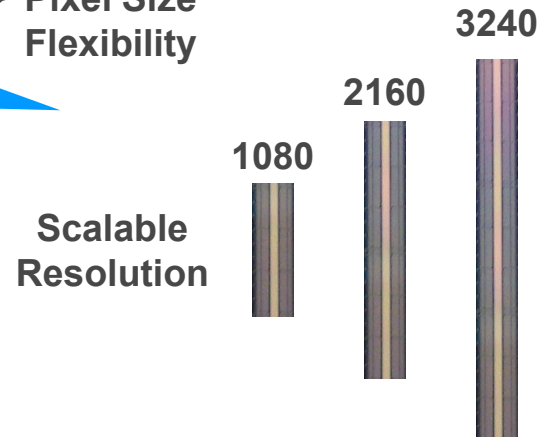
1080-Pixel GEMS Linear Array



6" GEMS Wafer



36 μm
or
18 μm } Pixel Size Flexibility

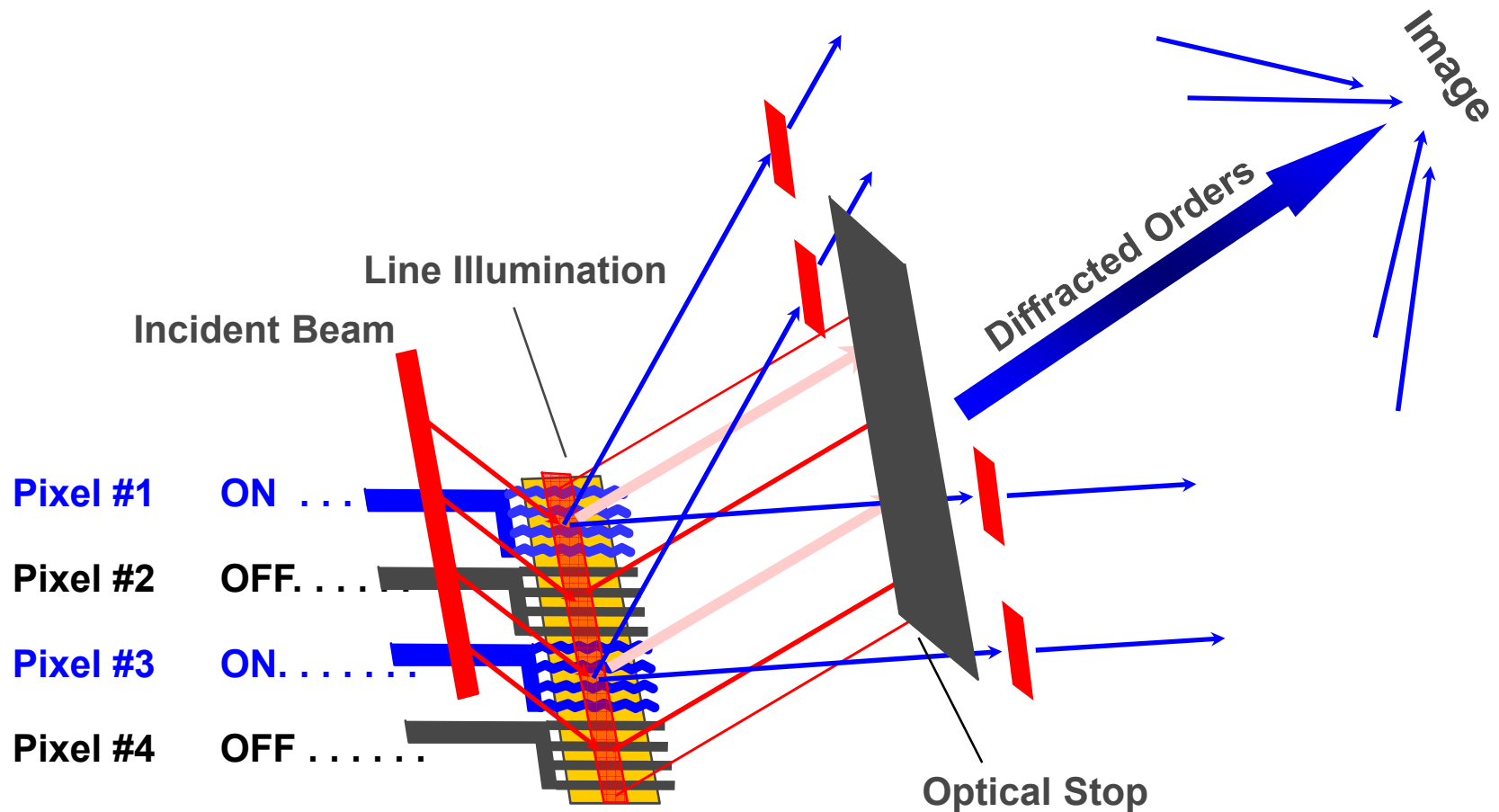


Very Wide Active Area Device
(10 mm x 20 mm active area)

Stitched Linear Array
(1 mm active area width)

Optical System Principles

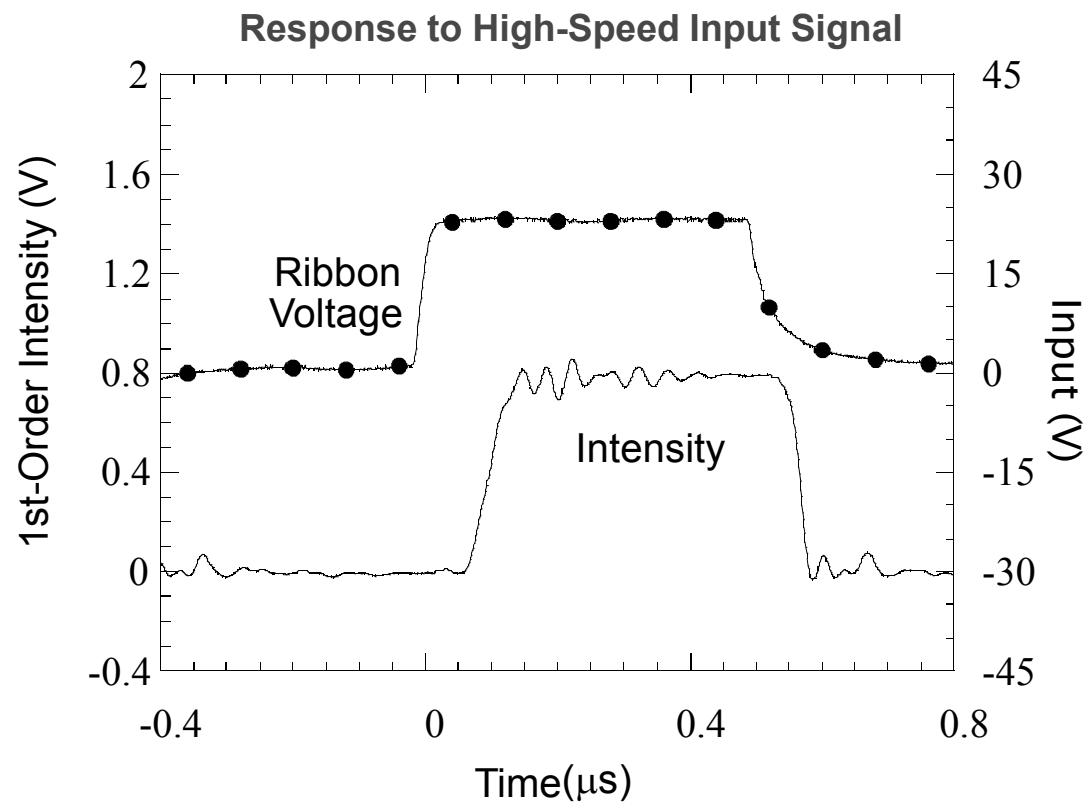
- OFF pixels reflect light, which is blocked by an optical stop
- ON pixels diffract light and the diffractive orders are collected to form a line image



GEMS Device High-Speed Response

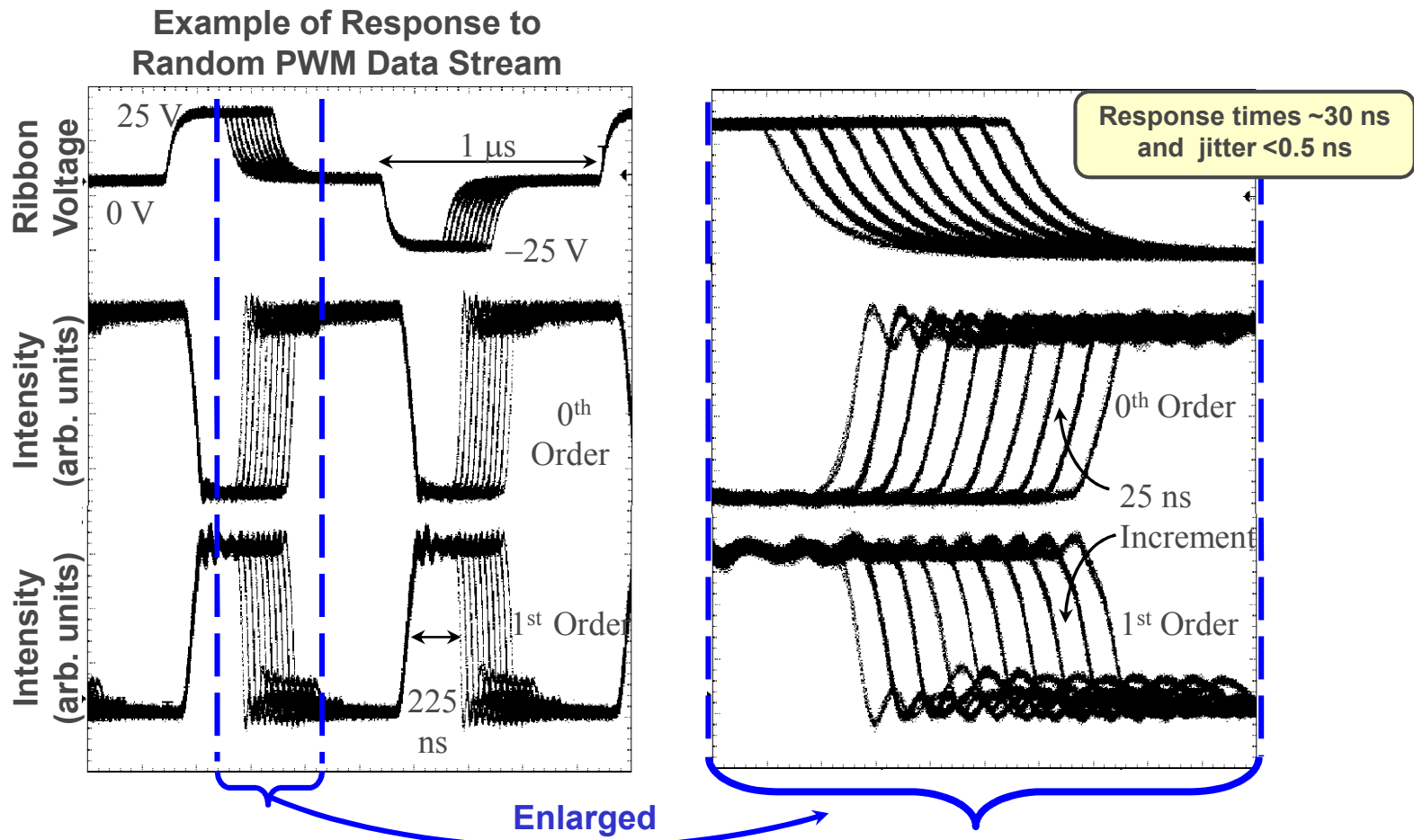
The fast switching speeds of the GEMS device enable a 2D display with a 1D linear array

~30 nanosecond digital operation

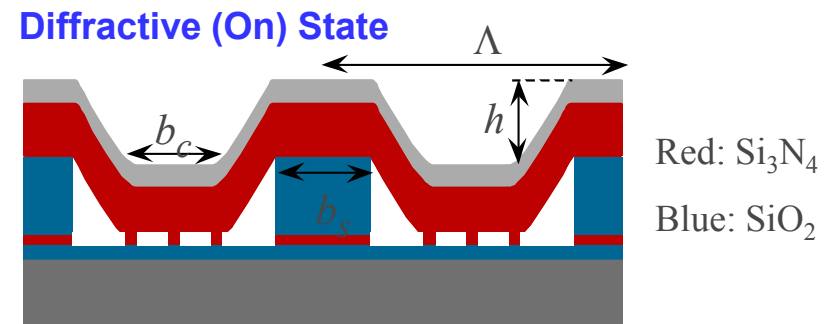
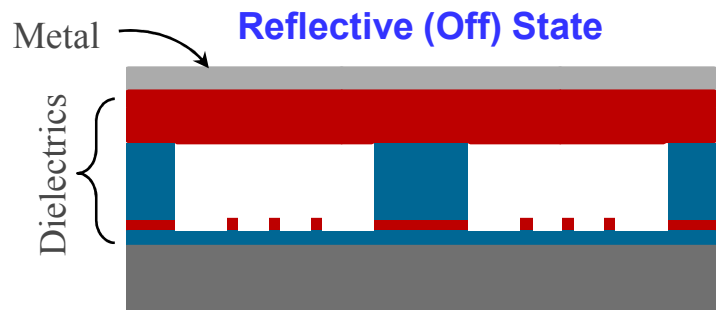
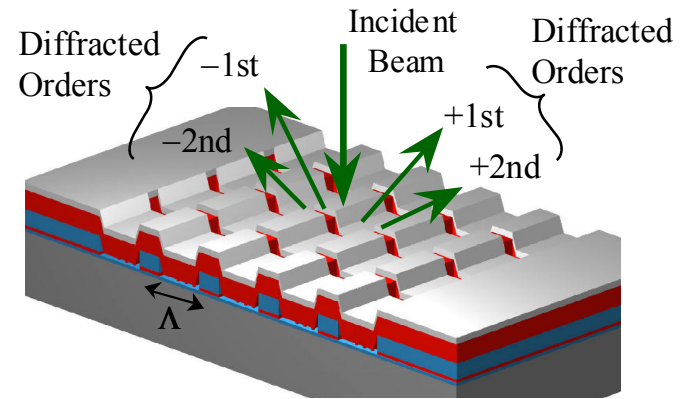
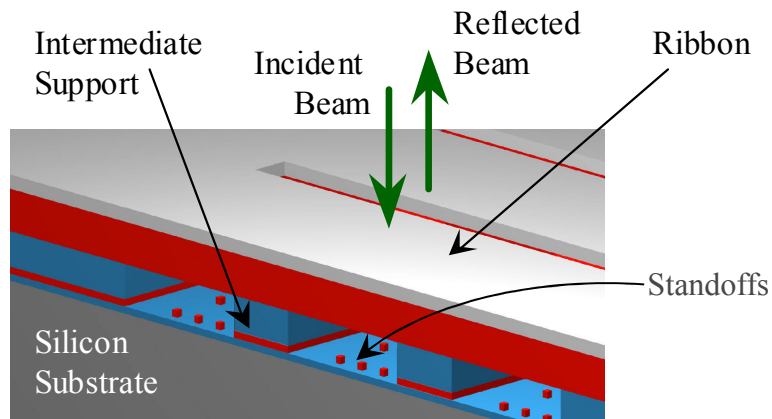


PWM Gray Scale Generation

The fast switching speeds allow for the generation of gray scale through pulse width modulation (PWM)



Opto-Electromechanical Device Model



- GEMS period (Λ)
- Support width (b_s)
- Channel depth (h)
- Ribbon width
- Ribbon gap
- Ribbon dielectric thickness
- Ribbon metal reflector
- Standoff separation
- Standoff height

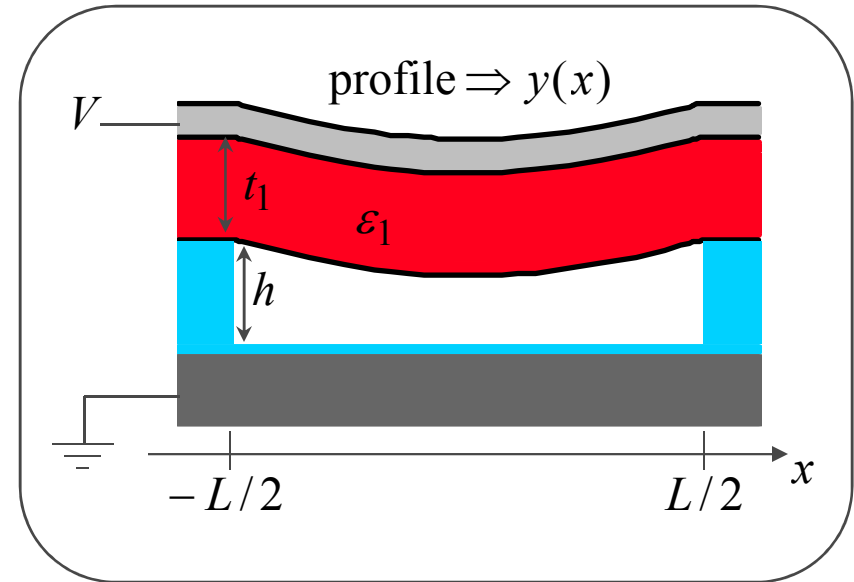
Opto-Electromechanical Model

1. Pull-down & operating voltage
2. Ribbon profile
3. Diffraction efficiency

Stress-Limit Ribbon Deformation Model

Stressed ribbon differential equation:

$$\cancel{\frac{EI}{dx^4} \frac{d^4 y}{dx^4}} - \overbrace{Sw \frac{d^2 y}{dx^2}}^{\text{tension}} = \overbrace{\frac{\epsilon_0 w V^2}{2(t-y)^2}}^{\text{electrostatic attraction}}$$



where

$\epsilon_0 \Rightarrow$ permittivity of free space

$\epsilon_q \Rightarrow$ relative permittivity of q th layer

$\sigma_n \Rightarrow$ stress of n th layer

$L \Rightarrow$ ribbon length, $w \Rightarrow$ ribbon width

$$S = \sum_n \sigma_n t_n \Rightarrow \text{tensile force per unit width}$$

$$t = h + \sum_q \frac{t_q}{\epsilon_q} \Rightarrow \text{effective electrostatic gap}$$

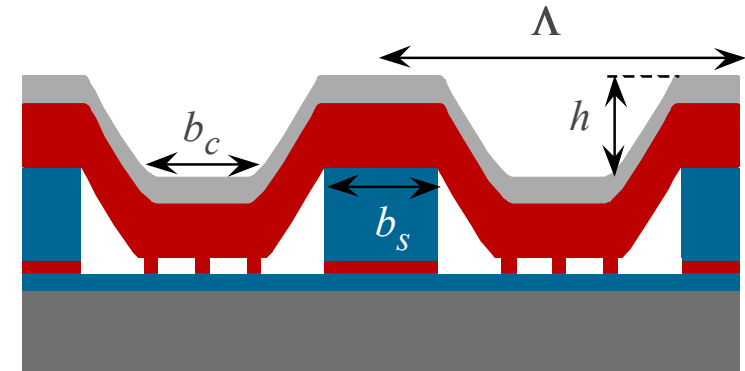
Analytical solution for ribbon profile and critical voltages

Device Model: Critical Voltages, Contact Length & Efficiency

Pull-down voltage:
$$V_{PD} = \frac{1.673}{L} \sqrt{\frac{St^3}{\epsilon_0}}$$

Release voltage:
$$V_{RL} = \frac{2}{L} \sqrt{\frac{S}{\epsilon_0}} \left[\sqrt{(t-h)th} + (t-h)^{3/2} \ln \left(\frac{\sqrt{t} + \sqrt{h}}{\sqrt{t-h}} \right) \right]$$

Contact length:
$$b_c = L(1 - V_{RL}/V) \text{ @ operating voltage } V$$

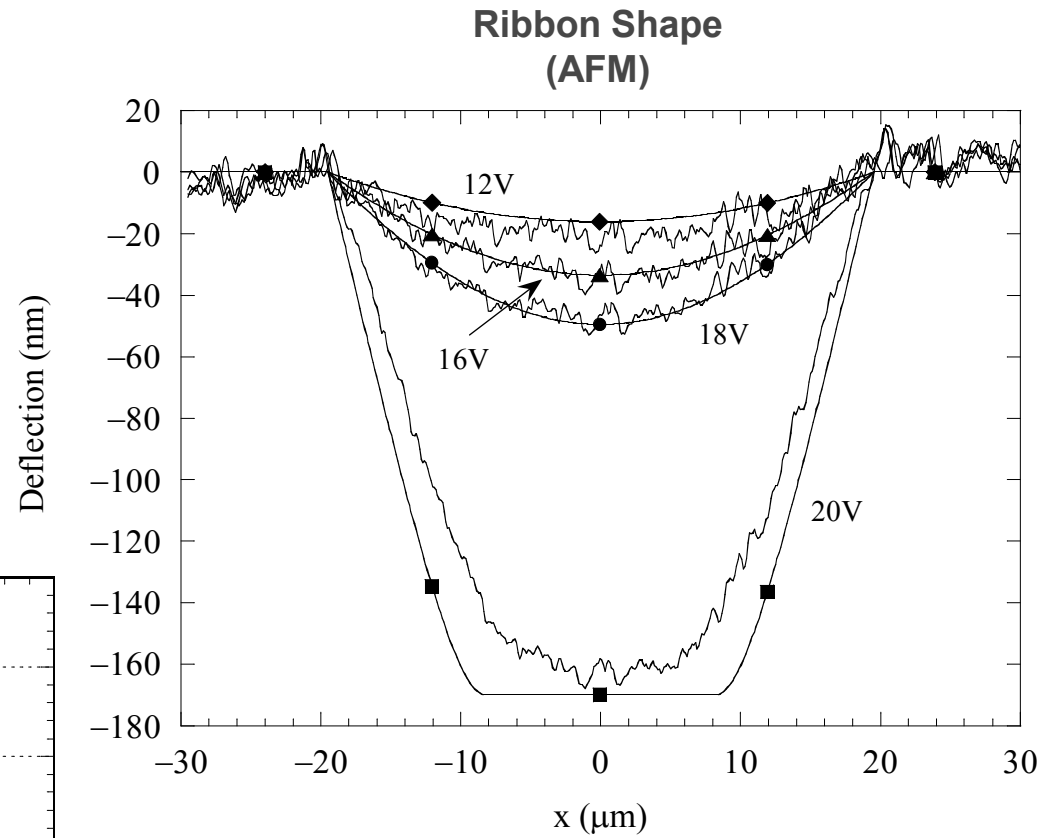
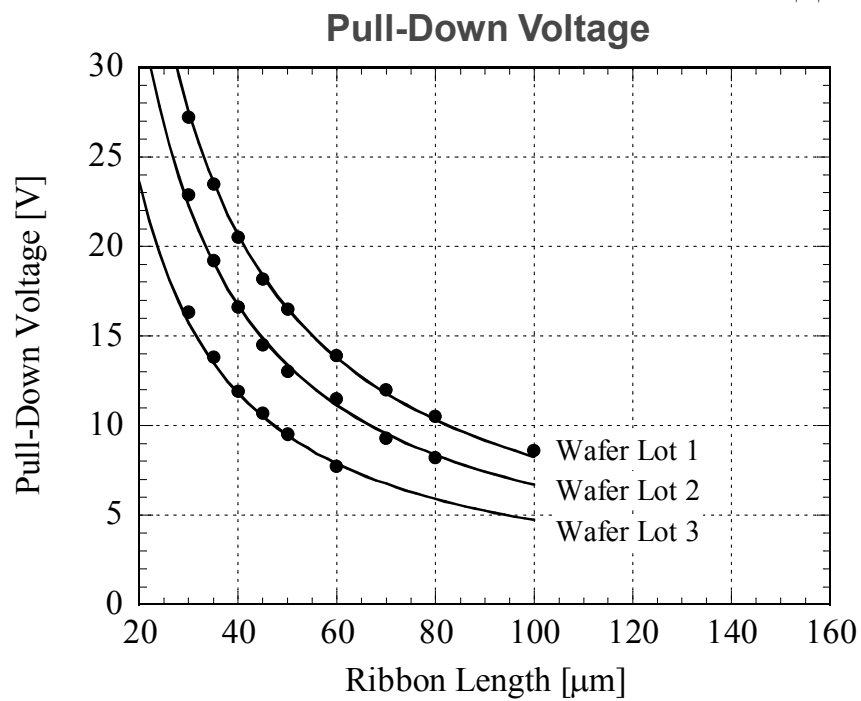


Nearly trapezoidal grating profile

Diffraction Efficiency:

$$\eta_m = \left| \frac{1}{\Lambda} \int_0^{\Lambda} e^{i4\pi y(x)/\lambda} e^{-i2\pi mx/\Lambda} dx \right|^2$$

Stress-Limit Model Versus Experiment



Laser Display

RGB Display Lasers (early 2000s)

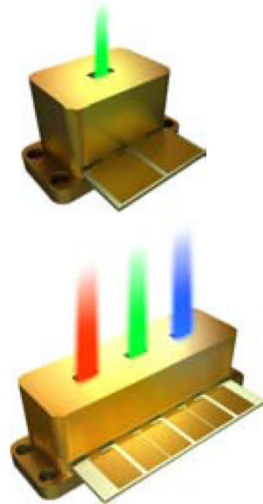


New RGB laser generator
(2nd generation) made by
JENOPTIK LDT.
Photo: JENOPTIK LDT

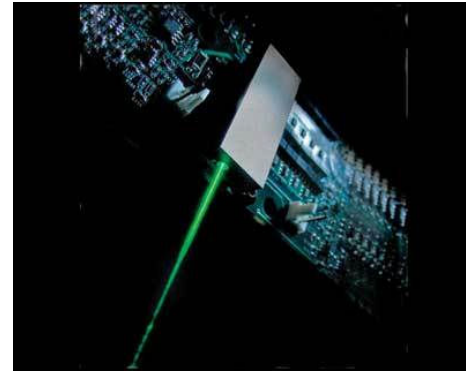
Compact RGB Display Lasers (now)

Novalux Necsel
(now Necsel)

Multi-Watt



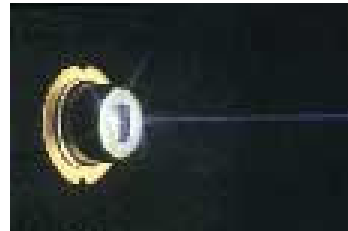
Corning Green Laser
(waveguide SHG)



100–300 mW

Nichia Blue Laser Diode

50 mW–1 W



**And many others
in development**
(OSRAM, Mitsubishi, ...)

Laser Projection Display

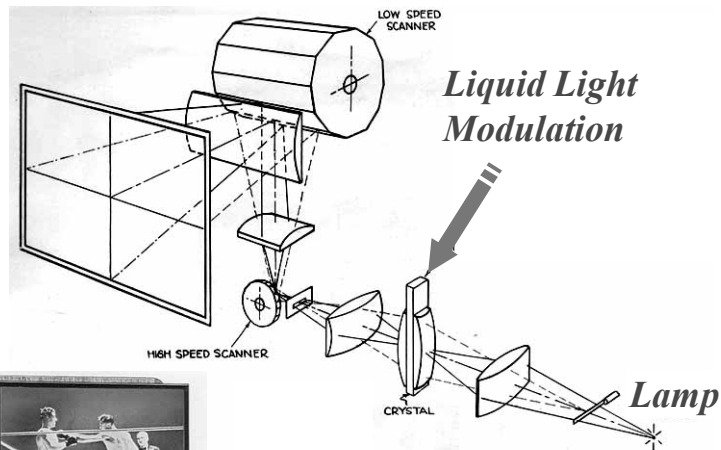
- Realization of low-cost, high-power RGB lasers enables
 - Projected images with large-screen diagonal (front or rear)
 - Color with extreme saturation, when desirable
 - Light source having long lifetime
 - Low cost per diagonal inch
 - Efficient use of light
 - High energy efficiency
 - Compact, lightweight systems

- A low-cost, high-performance light modulator is also required

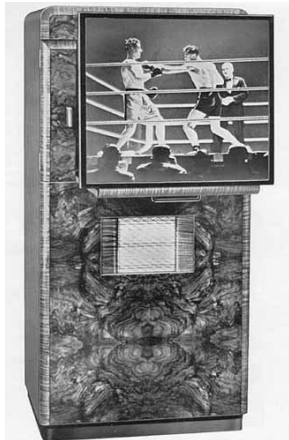
Modulator Options

- 2D Spatial Light Modulator and no scanner – e.g., DMD
 - Example: Mitsubishi Laservue TV (see laservuetv.com)
 - Challenging to achieve full HD resolution without artifacts at low cost
- No Spatial Light Modulator and 2D laser scanner – e.g., MEMS raster scanner with direct diode modulation
 - Example: Microvision pico-projector (see www.microvision.com)
 - Low-cost solution
 - Full HD challenged by scanner resolution and laser modulation speed
 - Difficulties with speckle reduction and laser power scalability
- 1D Spatial Light Modulator and 1D scanner
 - Resolution is easily scalable
 - Excellent image quality
 - Low-cost solution at high resolution

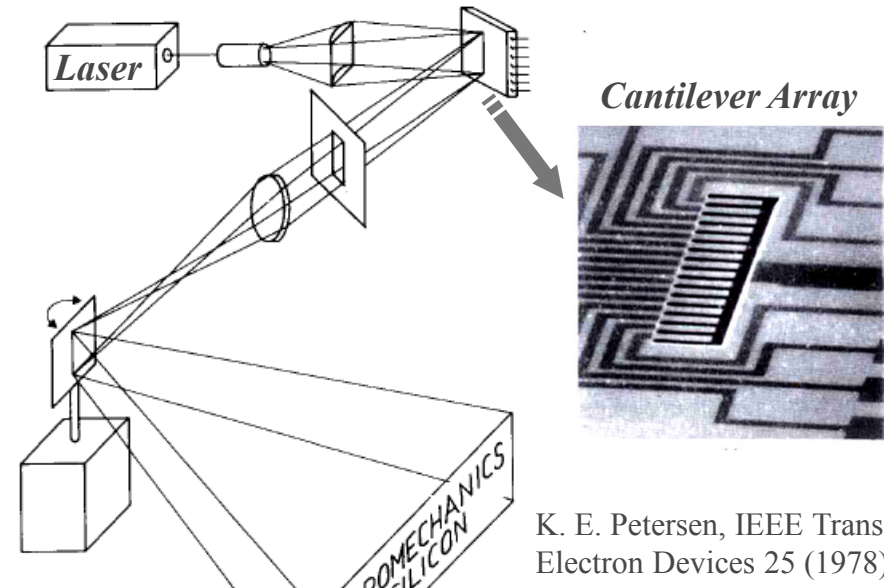
History: Scophony (1938)



Scophony Projection Television Manual
(www.tvhistory.tv)

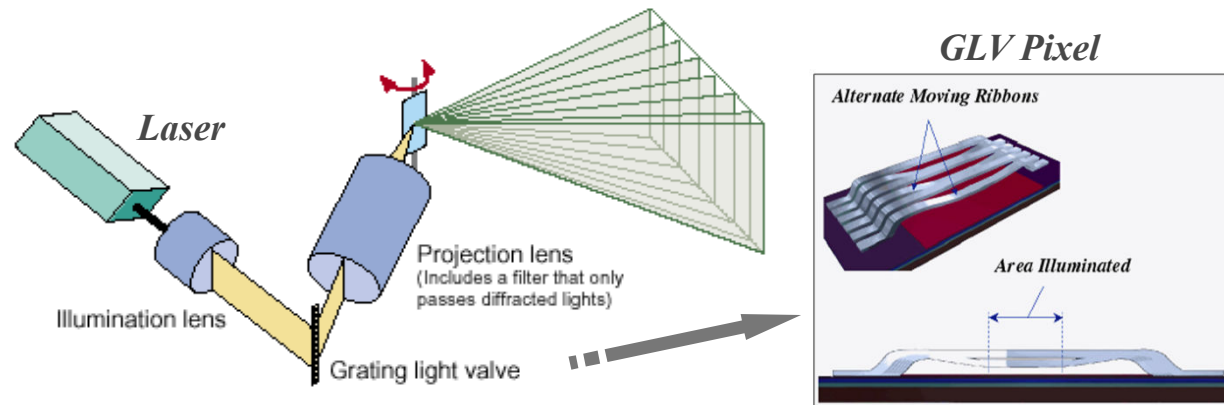


History: MEMS Cantilevers (1978)



K. E. Petersen, IEEE Trans. Electron Devices 25 (1978)

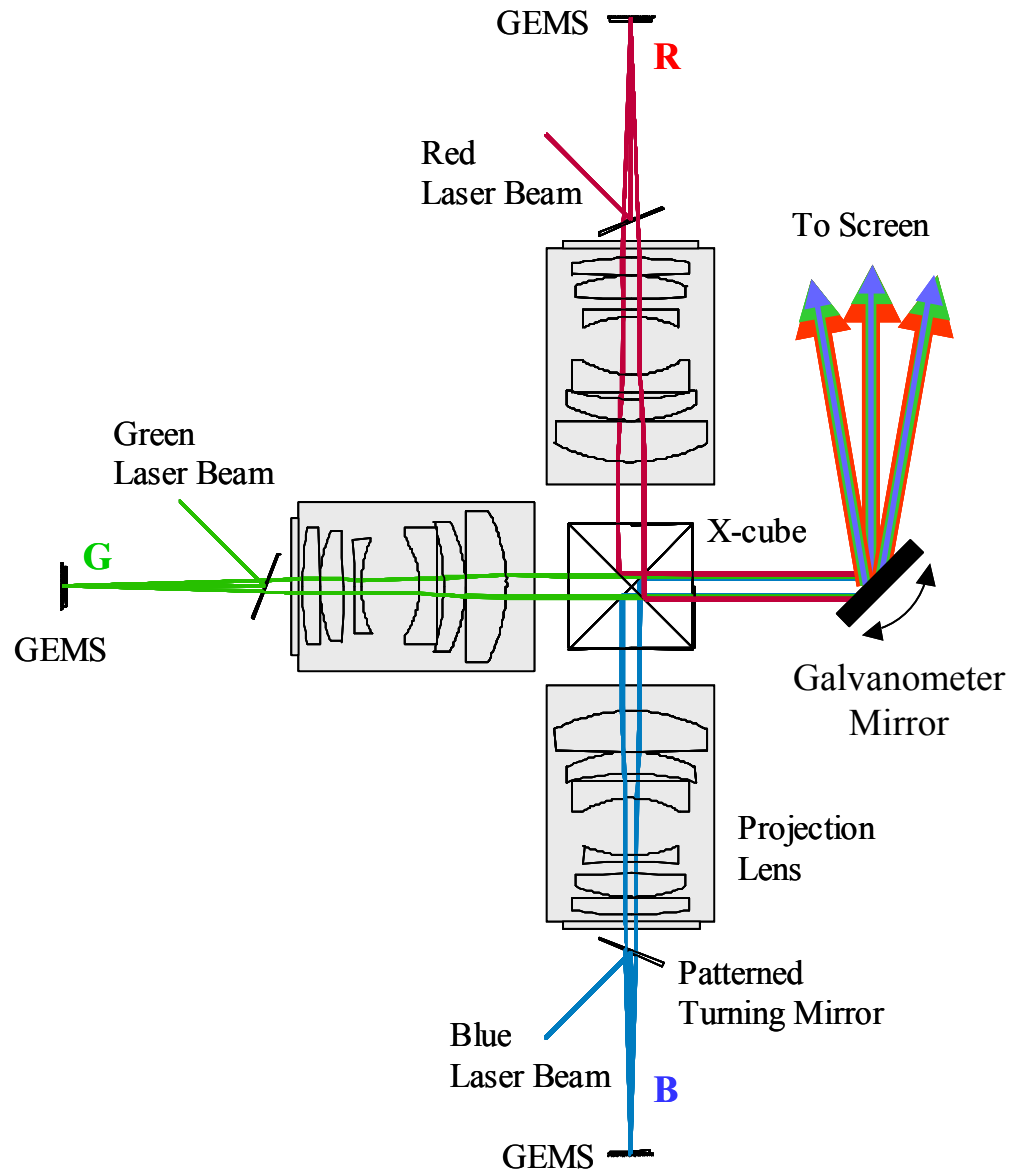
History: Grating Light Valve (1992 – Present)



Grating Light Valve Display Device, (Sony Corporation, 2002)

D. Corbin et al., *Grating Light Valve and Vehicle Displays*, (www.siliconlight.com)

Three-Chip Front-Projection Laser Display Prototype



Screen

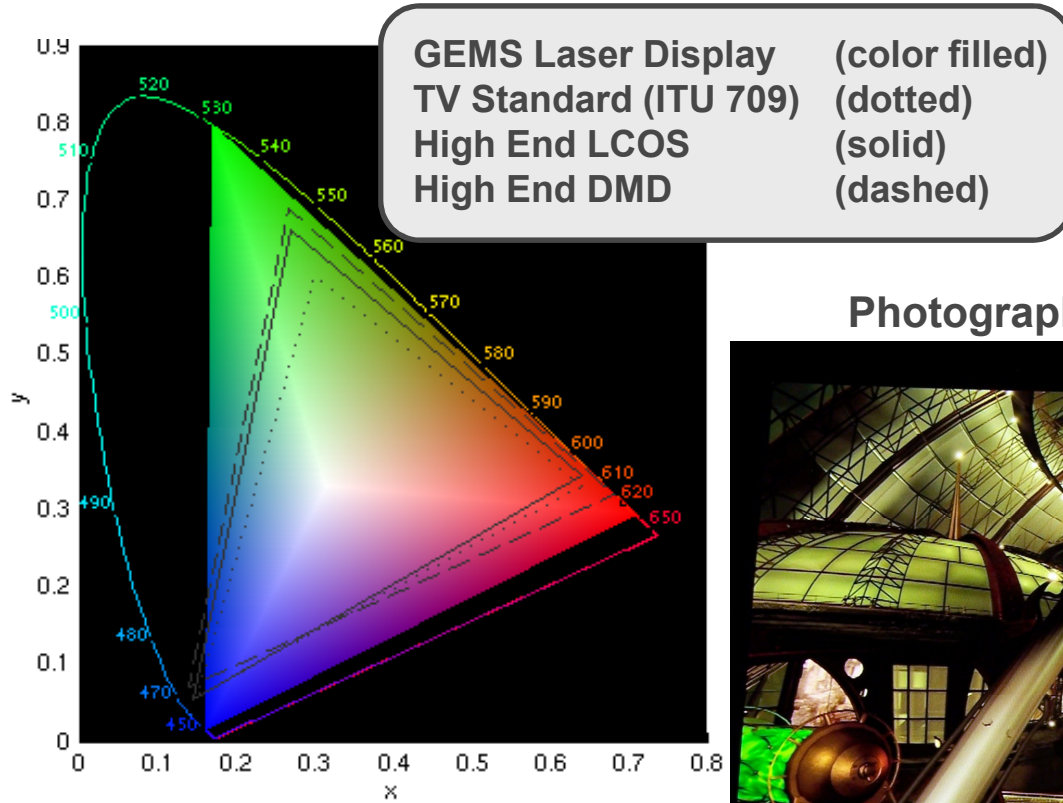
Resolution	1920 (H) 1080 (V)
Frame Rate	60 Hz
Screen Size	115 inch
Native Bit Depth	11 bit/color (PWM)
System Contrast	
<i>Frame-sequential</i>	>1500:1
<i>ANSI Checkerboard</i>	>250:1

GEMS Front-Projection Prototype: Photograph of Scene from Scanned Motion Picture Film



Image Color Setting: Natural Mode

Color Gamut

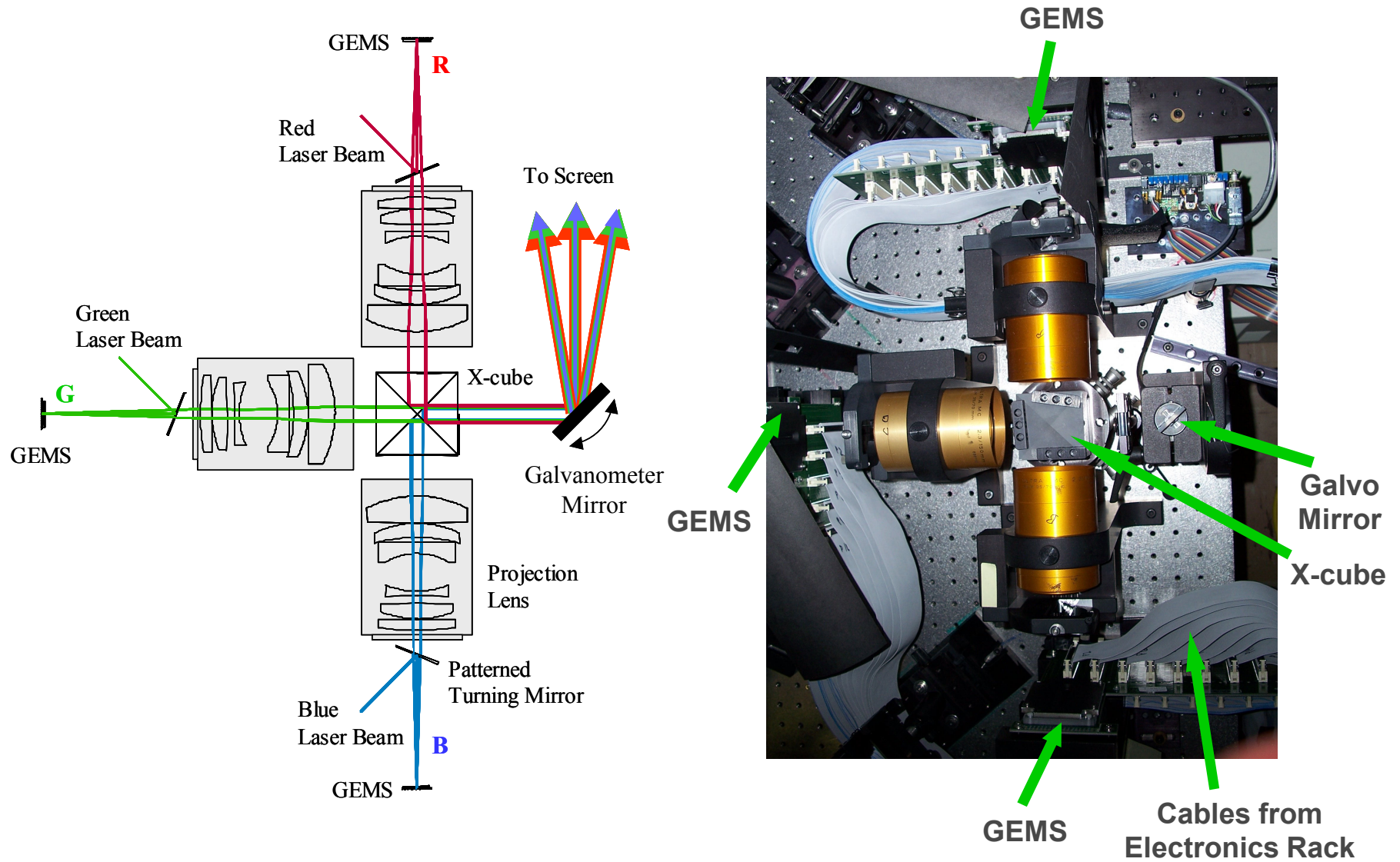


Photograph of Computer-Generated Imagery

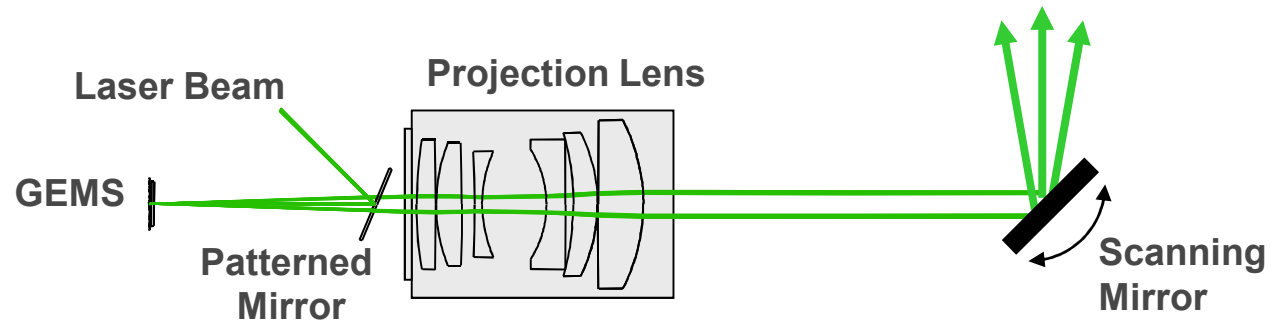


Image Color Setting: Full Gamut Mode

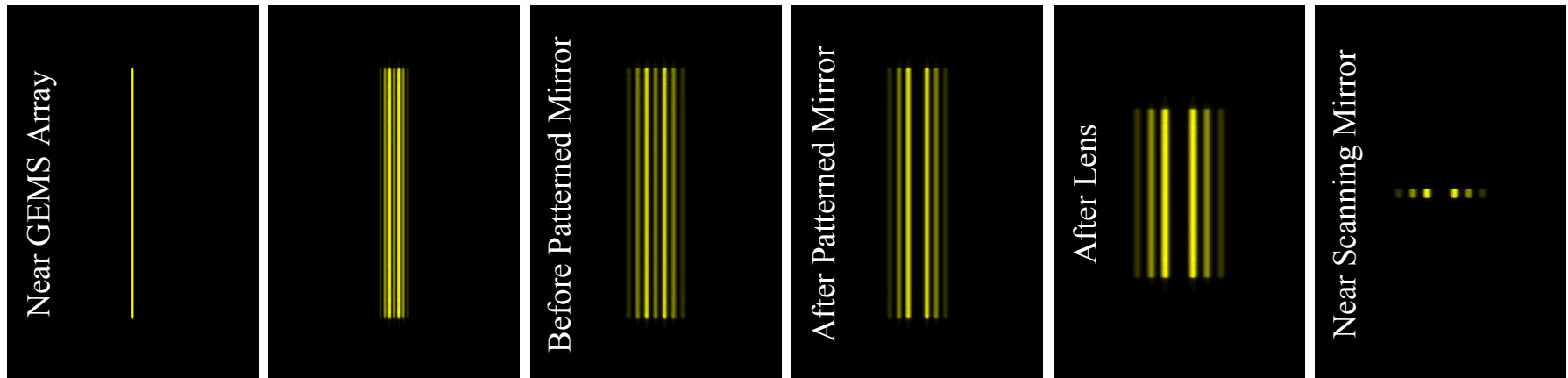
Three-Chip Front-Projection Laser Display Prototype



Propagation of Diffracted Light Beams

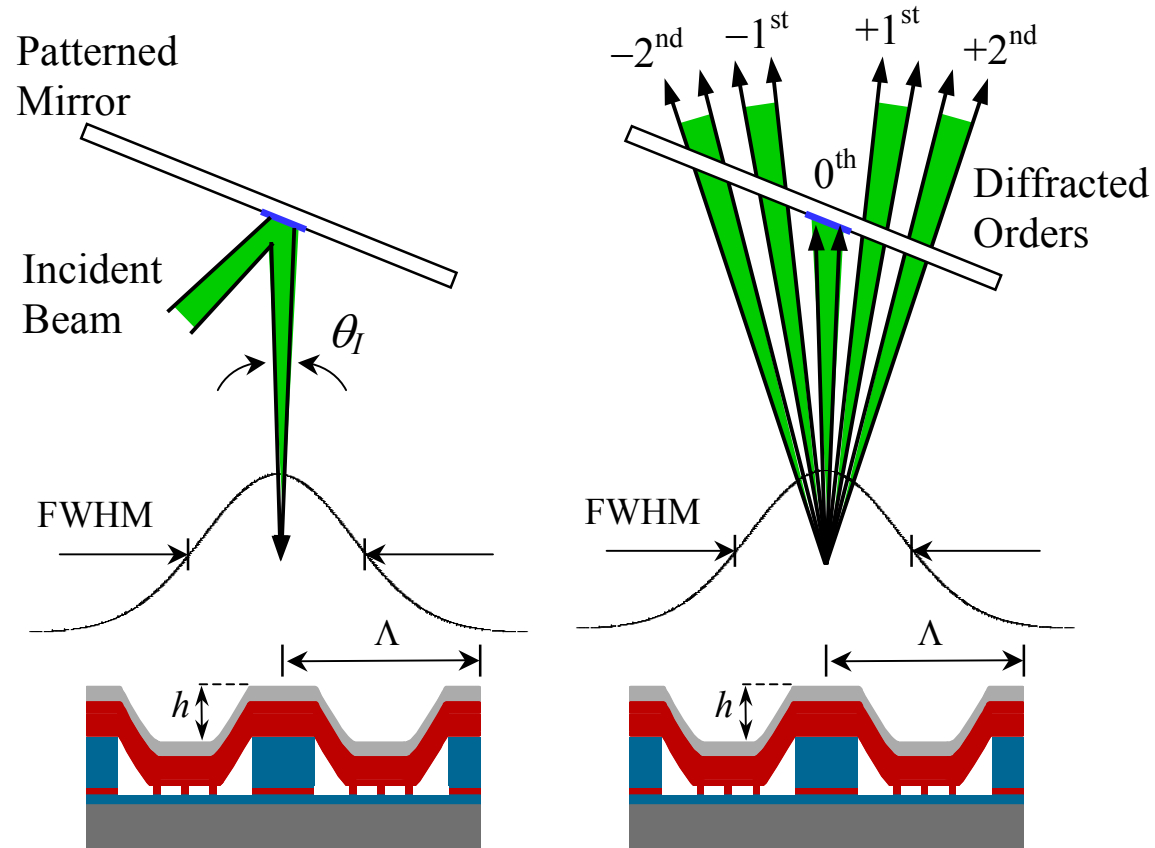


Light Propagation Model



- Perpendicular orientation of GEMS grating period enables
 - (a) Diffracted beams to be separated throughout system (except at image plane)
 - (b) On-axis illumination path before projection lens
 - (c) Collection of multiple diffracted beams with relatively small projection lens
- Small scanning mirror is placed near Fourier transform plane of projection lens

Separation of Diffracted Orders

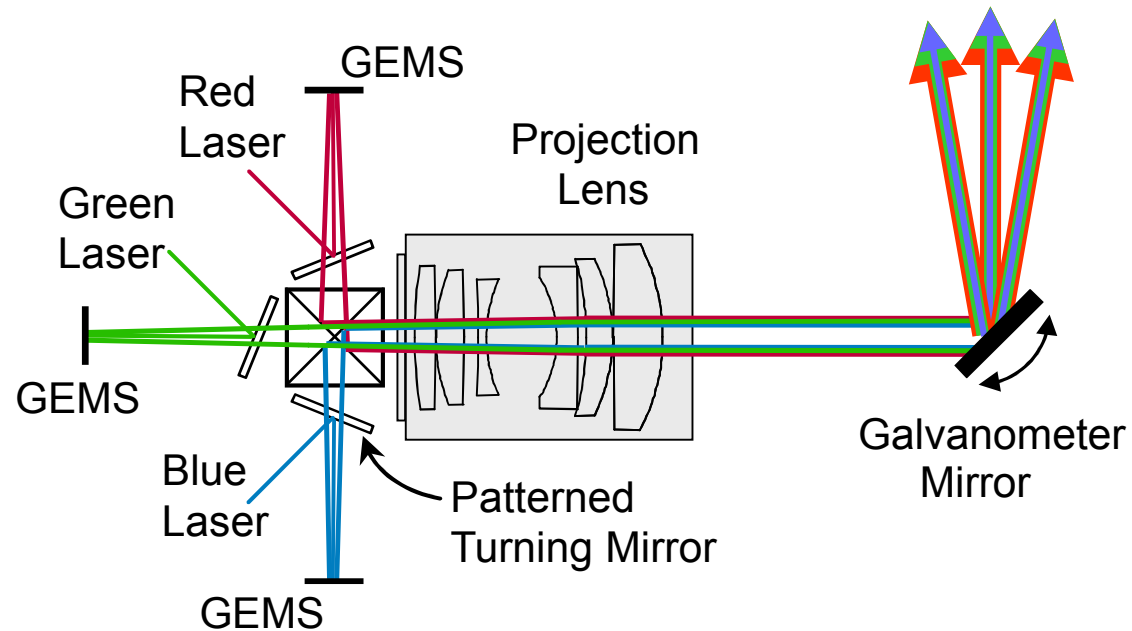


To separate diffracted orders: $\sin \theta_i < \lambda/\Lambda$

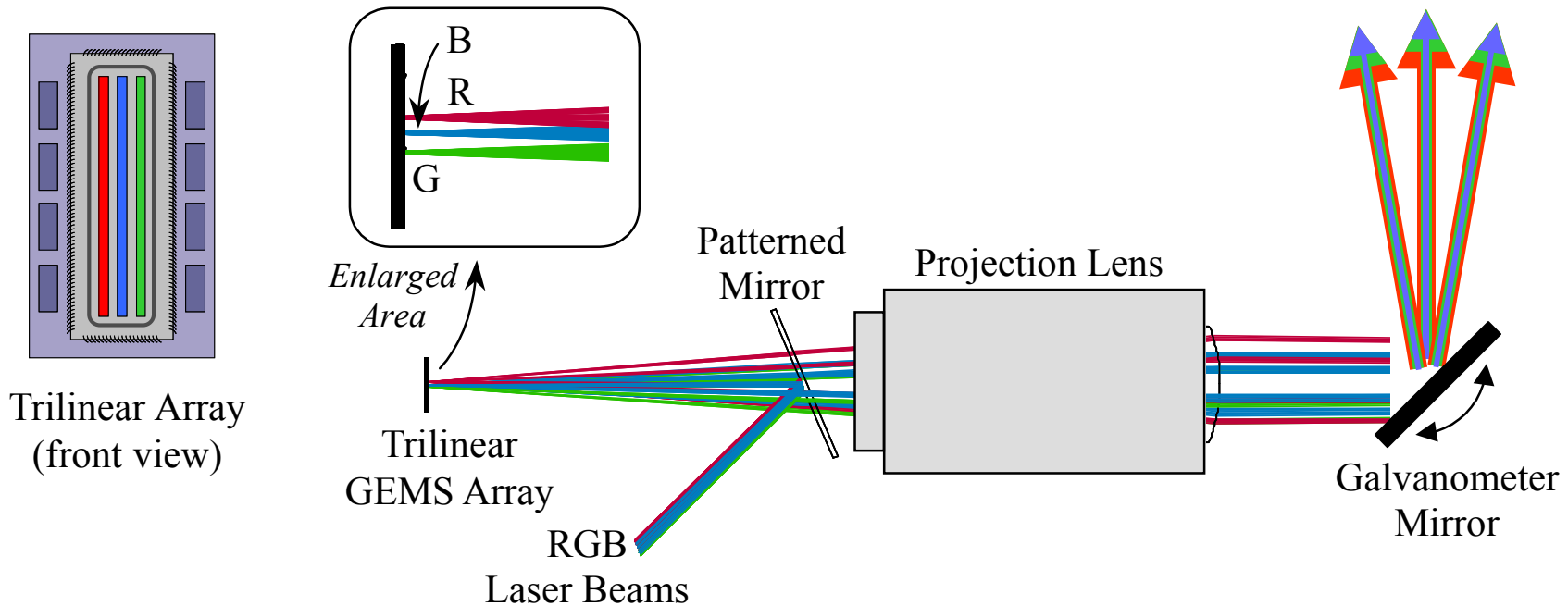
For a Gaussian laser beam: $\text{FWHM} \approx 0.55 \lambda/\sin(\theta_i/2)$

Therefore, $\text{FWHM} > 1.1 \Lambda$ [In practice $\text{FWHM} \approx 1.5 \Lambda$]

Laser Projector Architecture 1: Three-Chip System



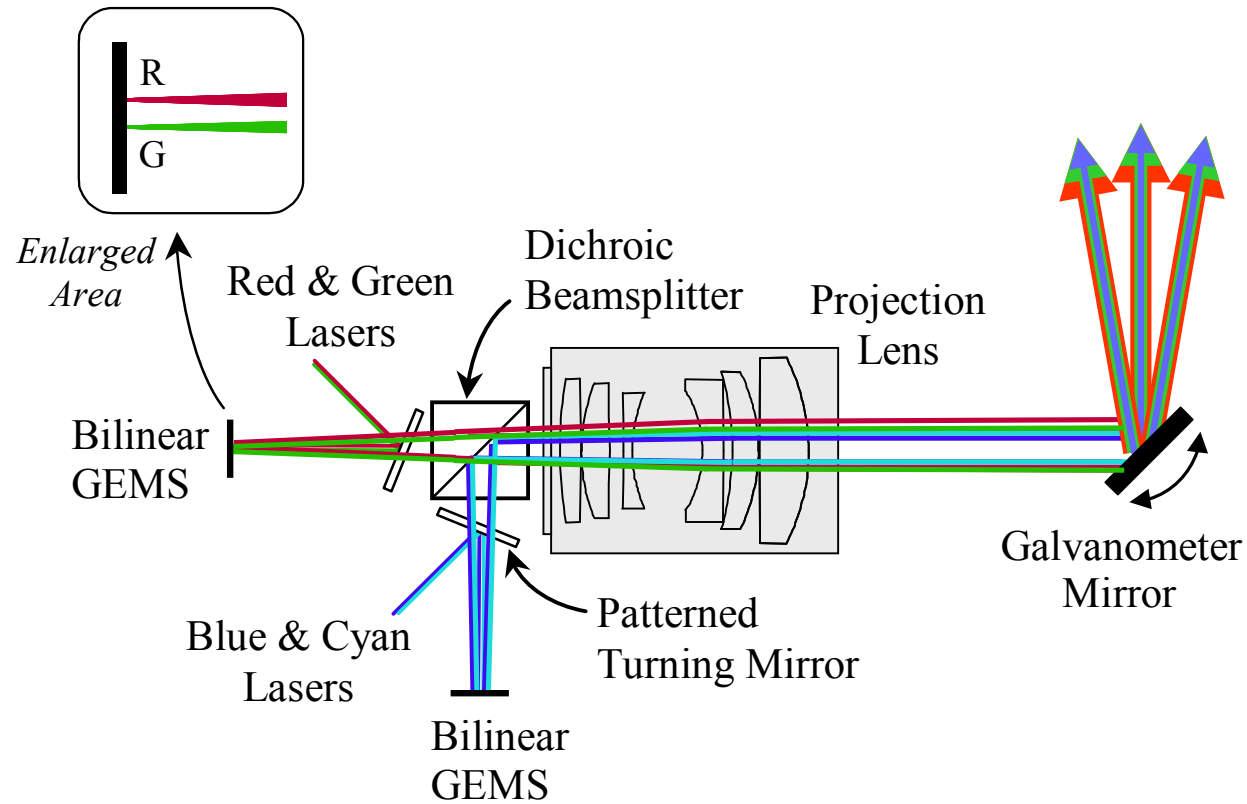
Laser Projector Architecture 2: Multilinear Array System



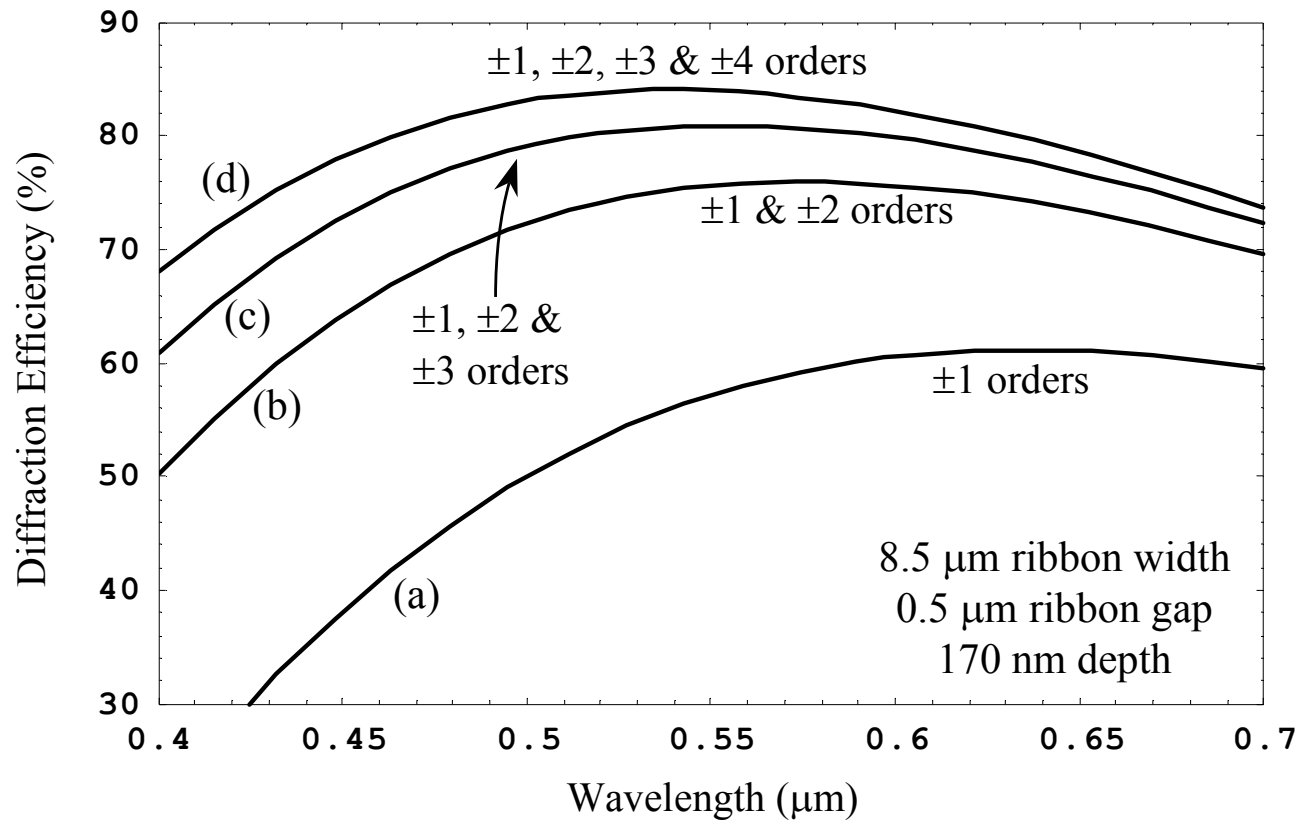
Combines advantages of three-chip architecture with those of single-chip architecture

- Simple optical architecture
- Maximum laser power utilization and brightness
- Best image quality

Laser Projector Architecture 3: Four-Color System with Two Bilinear GEMS Arrays



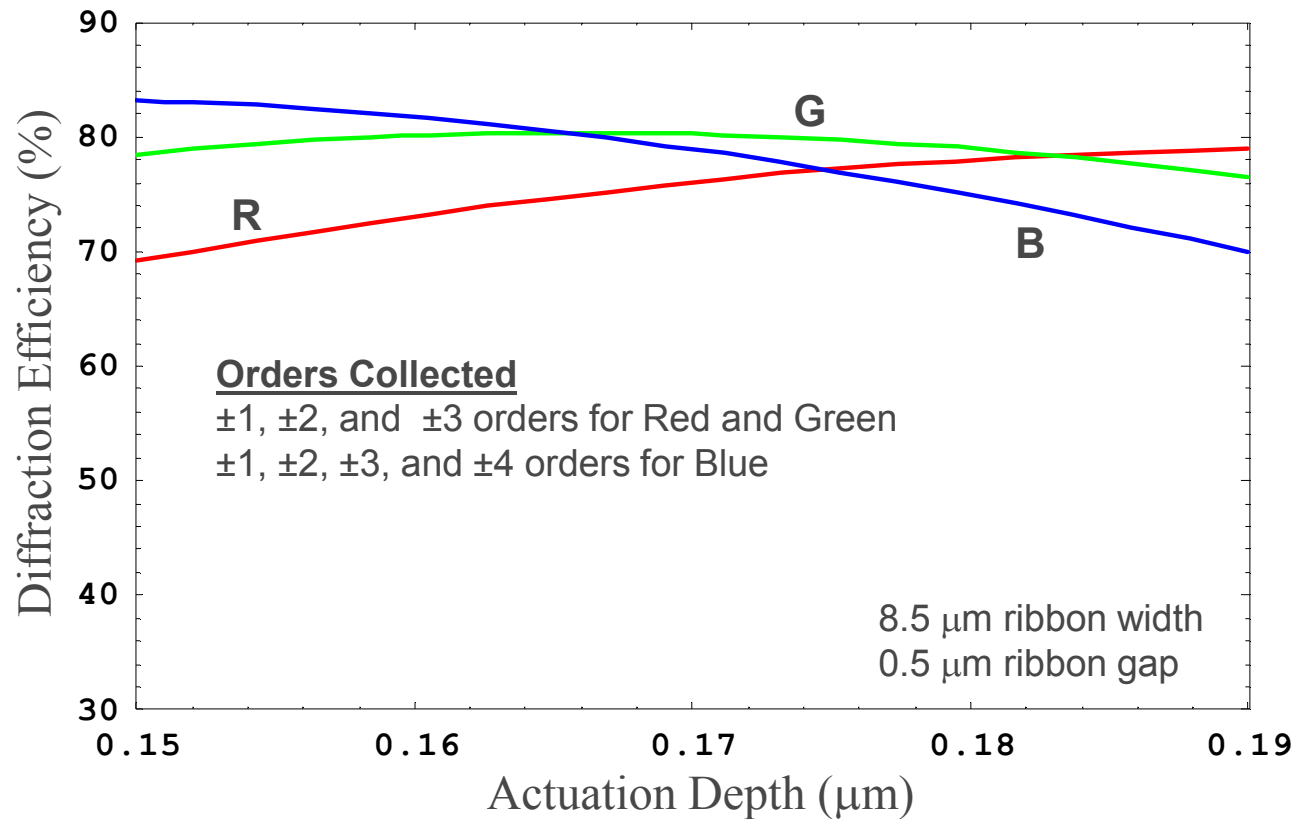
GEMS Device Efficiency Model



Optimized GEMS System Collects:

- 4 or 6 orders for Red (curve b or c)
- 6 orders for Green (curve c)
- 6 or 8 orders for Blue (curve c or d)

Device Efficiency Model for RGB System



Efficient GEMS device can be fabricated using the same design for all three colors

Note: RGB wavelengths are 630 nm, 530 nm, and 450 nm for model

GEMS Laser Projection System

Performance	Demo	Ultimate
Vertical Resolution (device pixels)	1080	2K – 4K
Horizontal Resolution (scan)	1920	4K – 8K
Frame Rate	60 Hz	60 Hz
Display Bit Depth (per color)	11 bit	>11 bit native
System Contrast (ANSI)	250:1	>500:1
System Contrast (frame-sequential)	1500:1	>5000:1
Data Stream Content	interlaced	progressive



Technology Benefits

High Image Quality

- Laser primaries for wide color gamut with bright, saturated colors
- Extremely high and scalable resolution for sharp, crisp images
- High native bit depth for billions of noise-free colors per pixel
- Reduced pixelization
- No motion artifacts

Simple GEMS-Based Design

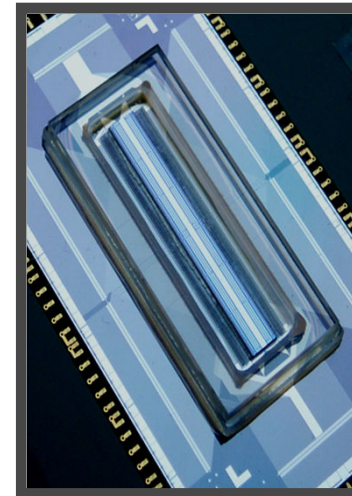
- Alignment and defect tolerant design
- Digital operation
- Compact optical components
- Low-cost modulator and optics

Extendable System

- Easily scalable linear array
- Programmable aspect ratio
- Flexible frame rate

System Architecture Options

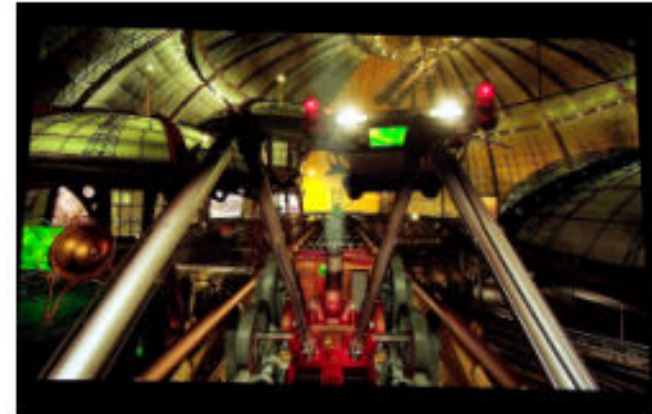
- Single chip or three chip
- Multilinear arrays for high performance at low cost



Potential Applications

GEMS Laser Display

- Front projection
- Rear projection laser TV
- Data visualization and simulation
- Command and control
- Panoramic workstations
- Heads-up displays
- Mobile projectors



Other Systems

- Laser printing
- Maskless lithography
- Light modulation
- Programmable spectral imaging
- ...



PROGRAMMABLE SPECTRAL IMAGING

Multispectral Imaging: Introduction

Multispectral imaging systems are used in a variety of applications where conventional RGB imaging does not adequately reveal spectral features of interest.

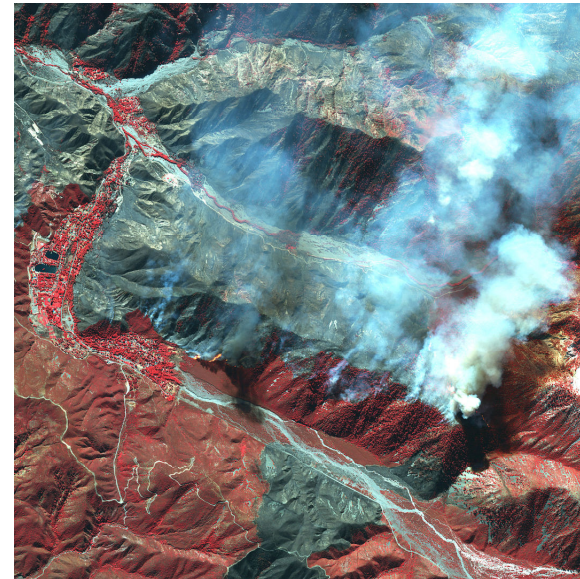
- *Application areas: remote sensing, medical, and biological imaging, ...*

For example, the 4-band multispectral image below shows vegetation regions (false red) that are not visible in the natural color image.



DigitalGlobe

**3-Band Natural Color
Image of Forest Fire**

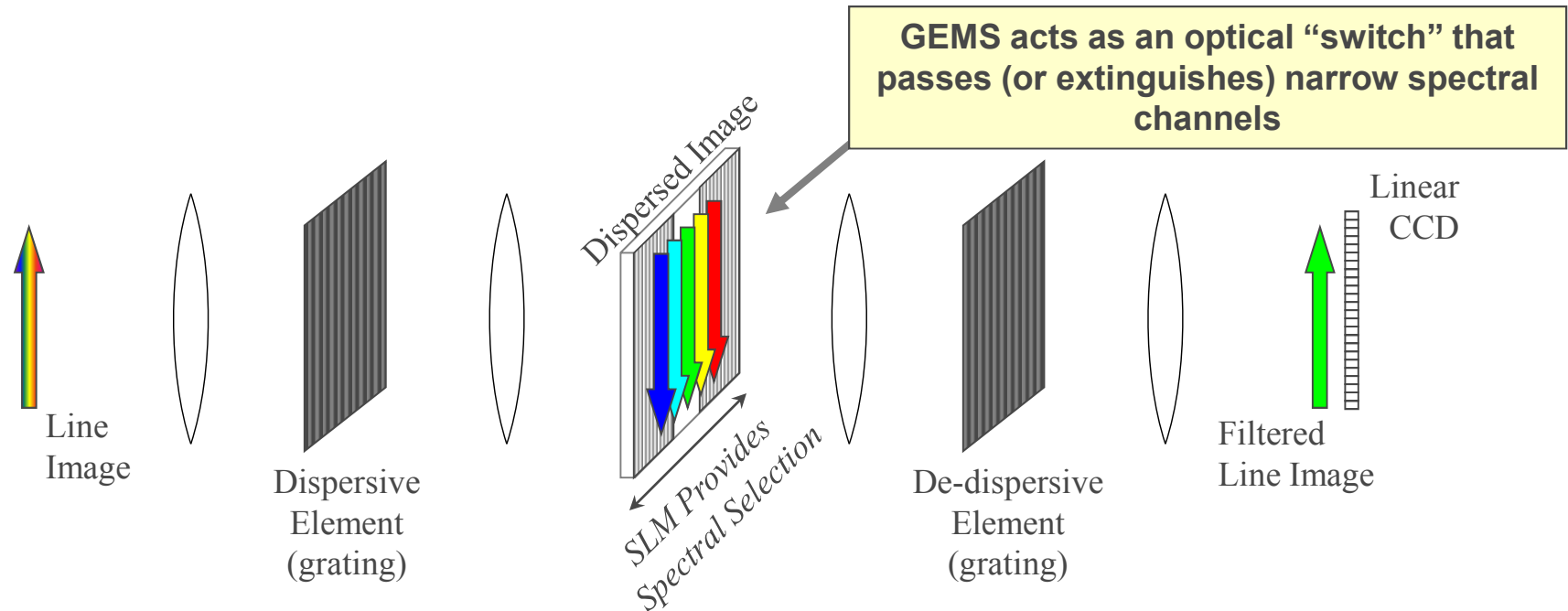


DigitalGlobe

**4-Band Image of Forest Fire
with False Color Infrared**

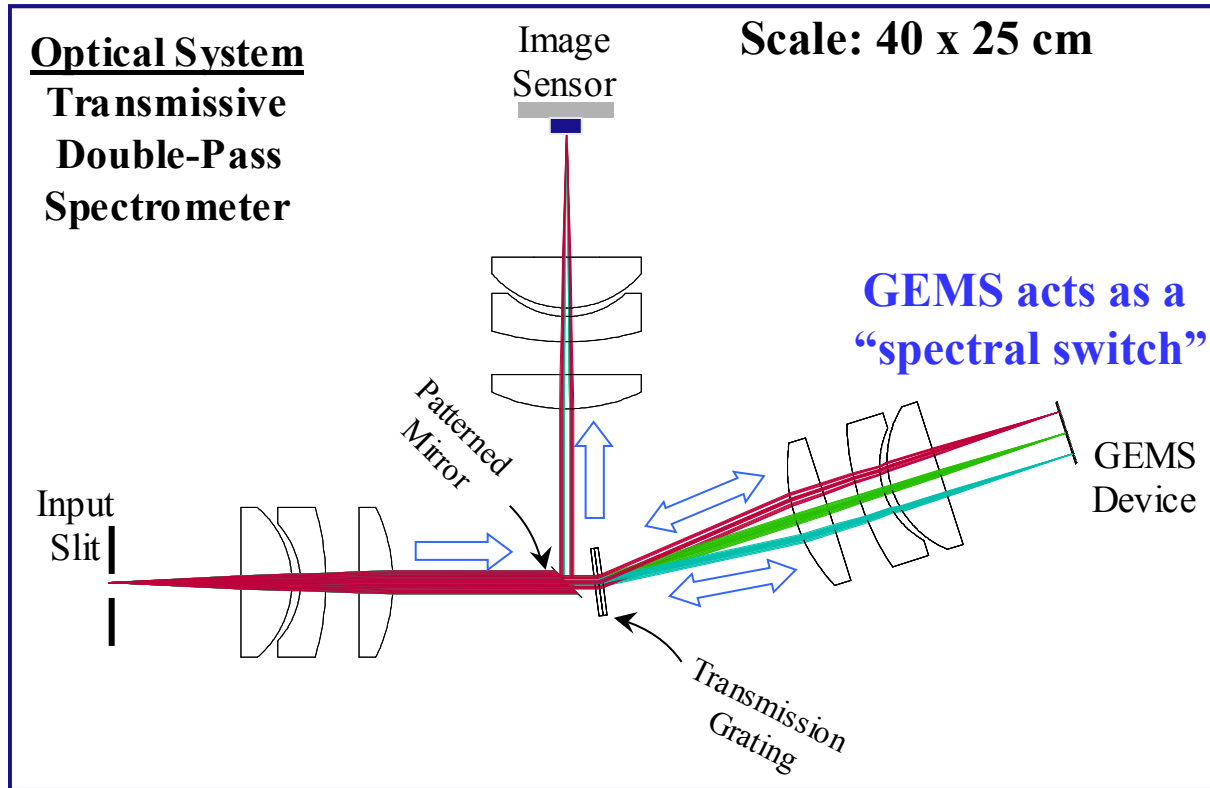
Challenge: Create an imaging system with a programmable spectral transmission function that provides high-resolution line-scanned imaging.

System Concept

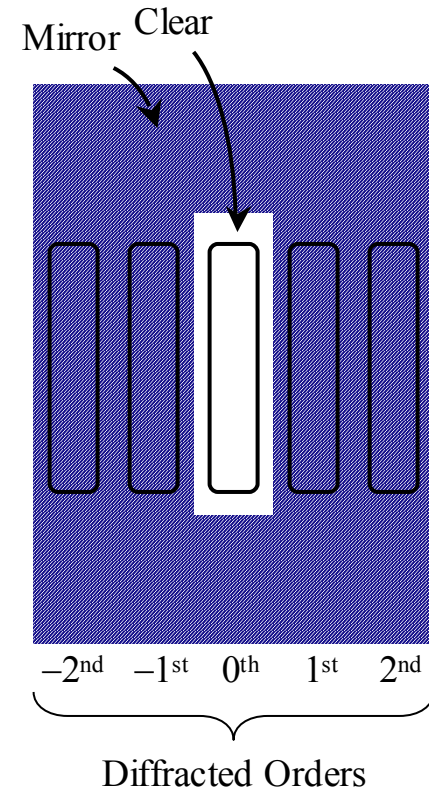


- Spectral band selection approach:
 - Line image dispersed by a grating onto a **Spatial Light Modulator (SLM)**
 - Electronic control of SLM provides selection of wavelength bands for imaging
 - Selected bands are de-dispersed and re-imaged on a detector array
- 2D image is captured by line scanning across object of interest

GEMS-Based Programmable Spectral Imager



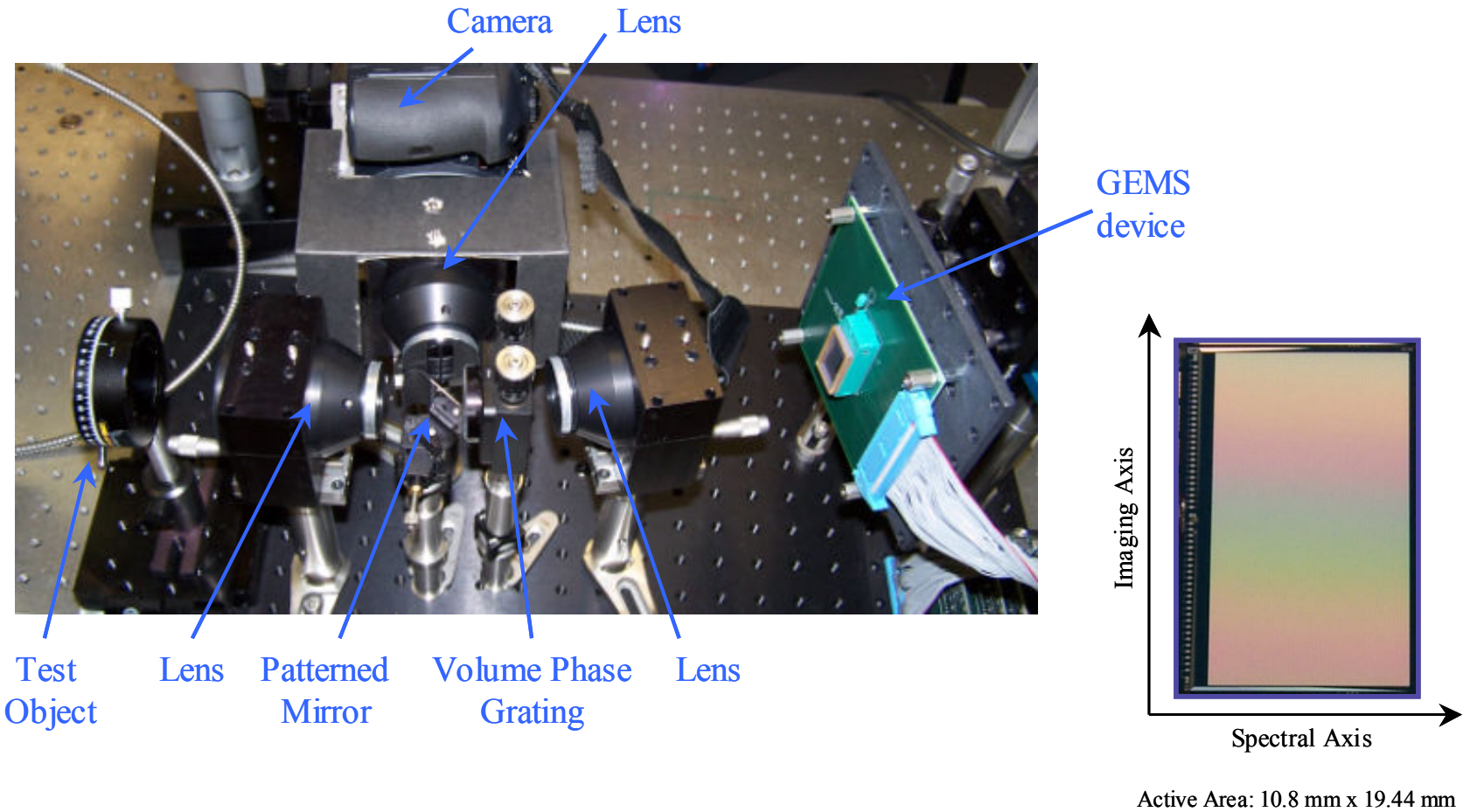
Patterned Mirror



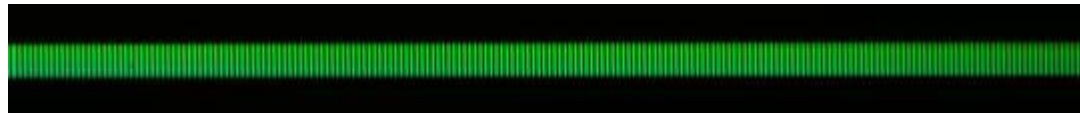
Key Features

- High-speed spectral tuning
- Excellent image quality
- 32 spectral bands (current configuration)
 - 450–566 nm: 12 bands with ~10 nm bandwidth
 - 566–634 nm: 14 bands with ~5 nm bandwidth
 - 634–692 nm: 6 bands with ~10 nm bandwidth

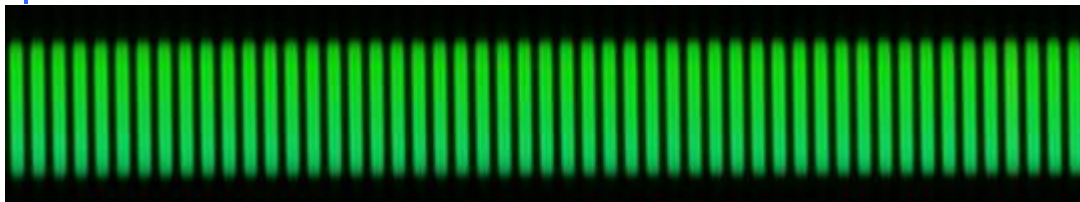
Spectral Imager Breadboard



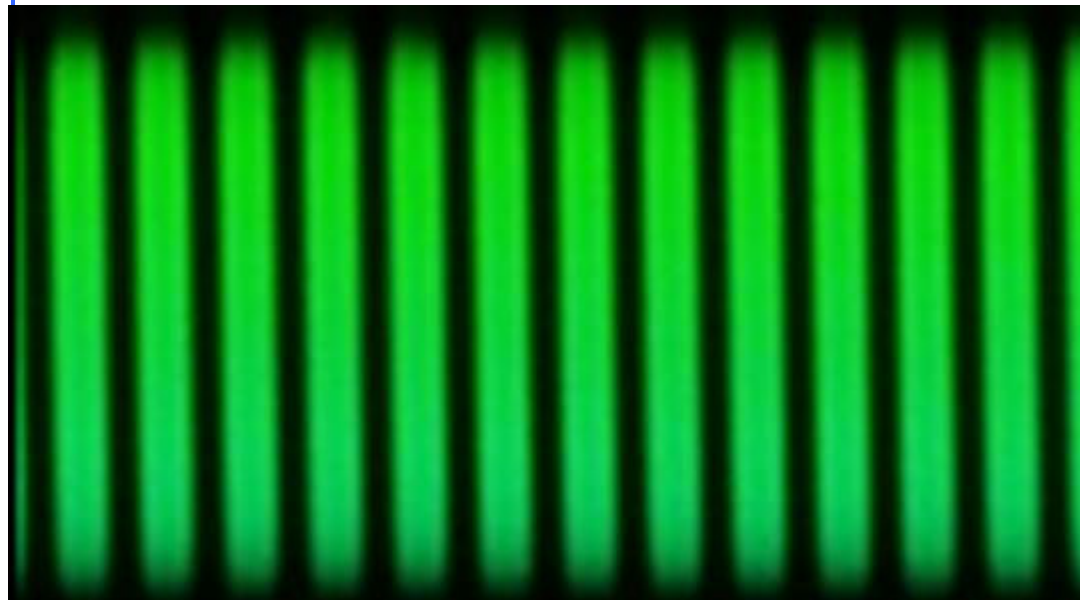
Breadboard Image Quality



Entire Image
(17 mm of 19.44 mm)



Enlarged 4X



Enlarged 16X

Test Object
Ronchi ruling (12 lp/mm)
Camera
Olympus E-1 (5 megapix)

Spectral Selection with Slide Translation



Red Band
(20 nm)

Green Band
(20 nm)



All Bands



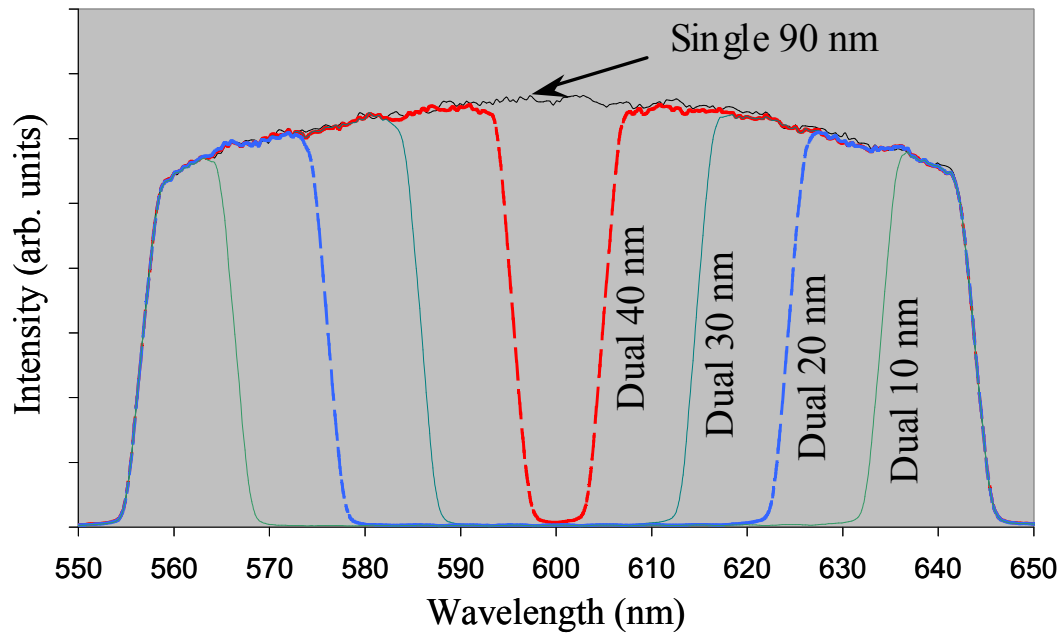
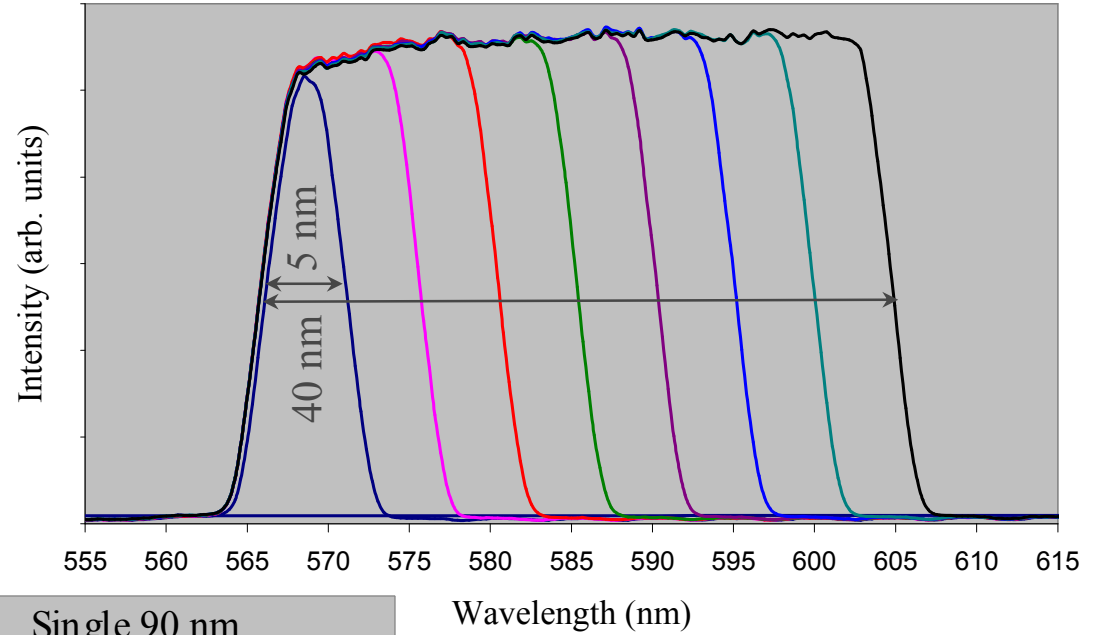
Blue Band
(20 nm)

Red & Blue Bands
(20 nm each)



Fully Programmable Spectral Bands

Programmable Bandwidth



Multiple Programmable Spectral Bands

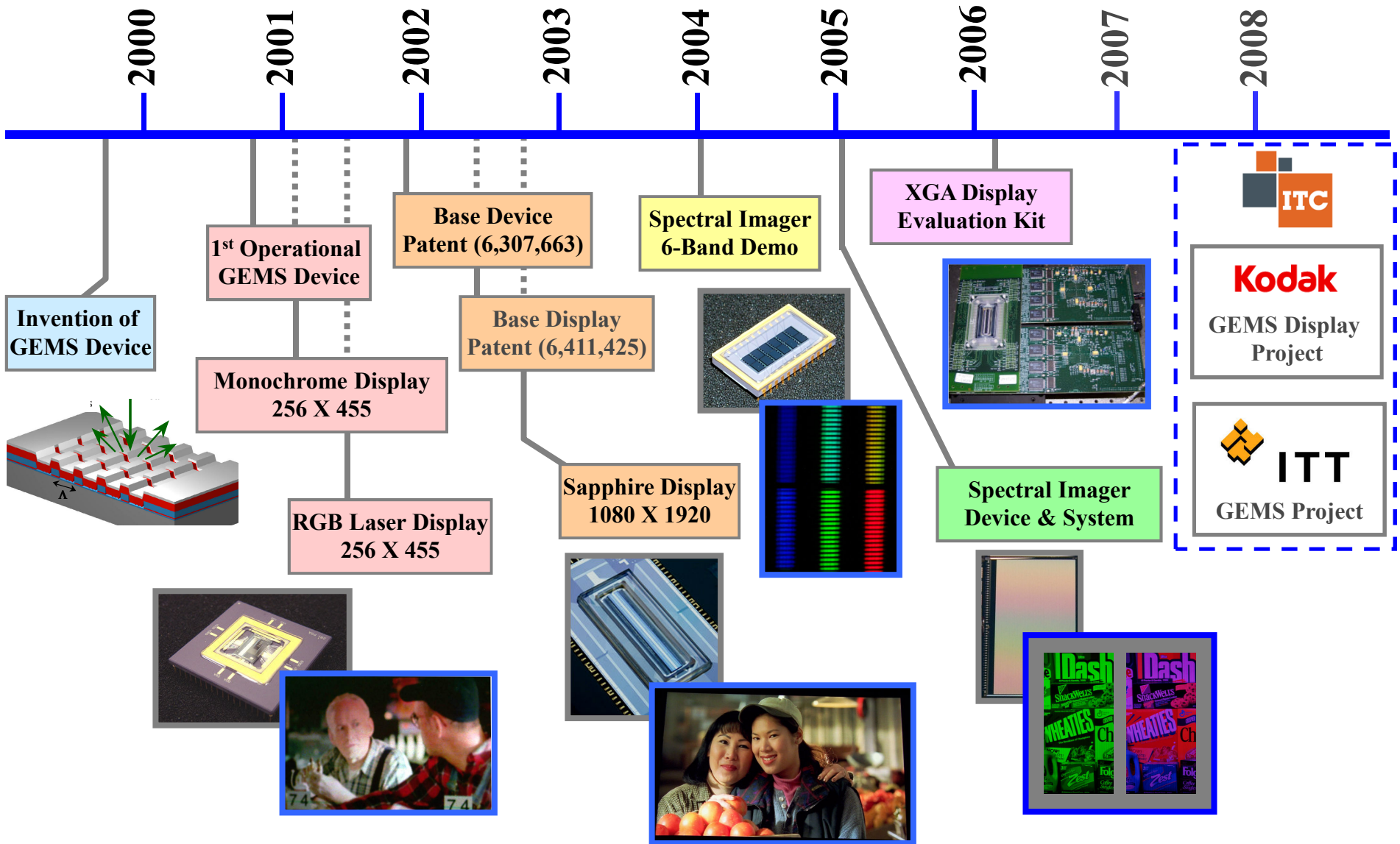
An Interesting Combination...

Programmable Spectral Imaging and Broad Gamut Display
Both with GEMS-based Systems



GEMS Technology: Timeline and Milestones

Grating ElectroMechanical System



ITC MEMS Wafer Fab



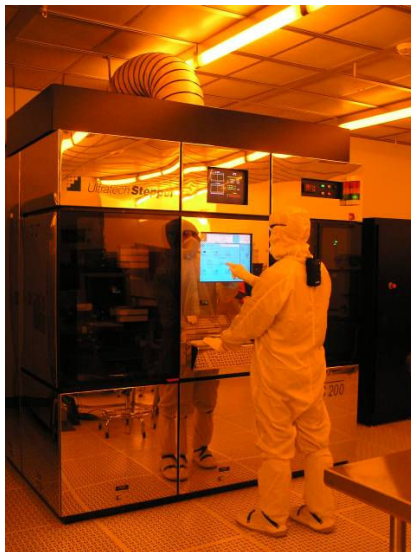
Ultratech Nano160
(1X projection; backside alignment)



**TEL Mark VII Coat/
Develop Track**

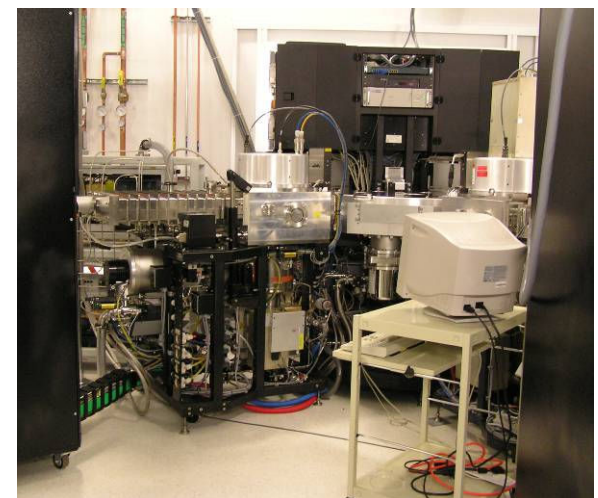


**LPCVD and Atmospheric
Furnace Processes**



**Ultratech XLS
Stepper**
(4X projection;
0.35 μm
resolution)

**Chemical-
Mechanical
Polishing
and Grinding**



Veeco 3-Chamber Sputter Tool

ITC MEMS Wafer Fab



Leybold Reactive Evaporator
for Optical Glasses

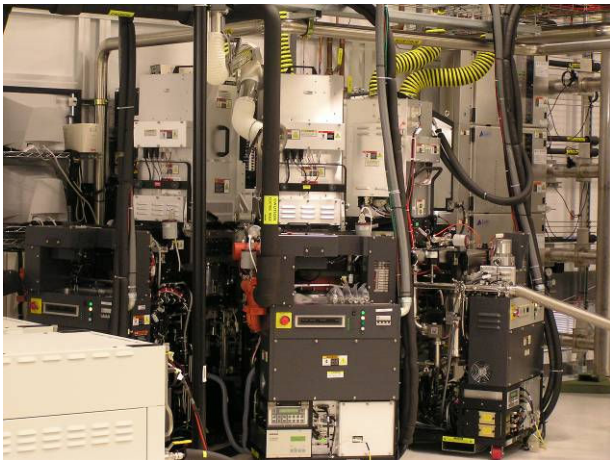


Xactix XeF2 Sacrificial Etch



STS Si
Deep RIE

LAM Alliance
Cluster Tool



ITC MEMS Packaging

Suss ABC200 Automated Wafer Bond Cluster



Suss FC150

Flip Chip Bonders



SEC 860 Omnibonder

Plating Bench



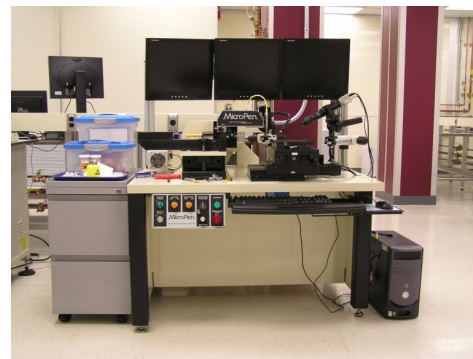
ADT 7200 Automated Dicing Saw



Asymtek Automated Fluid Dispensing system



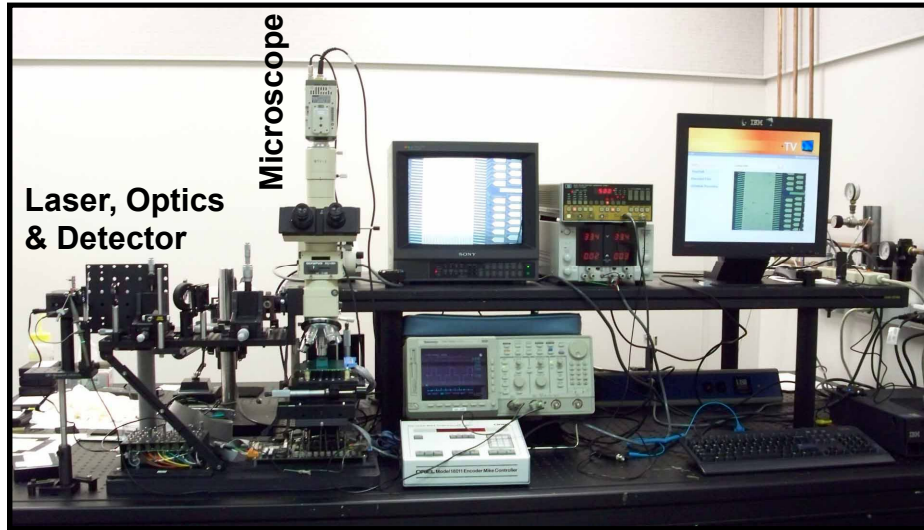
Ohmcraft Micropen



Hesse & Knipps Automated Wedge Wirebonder



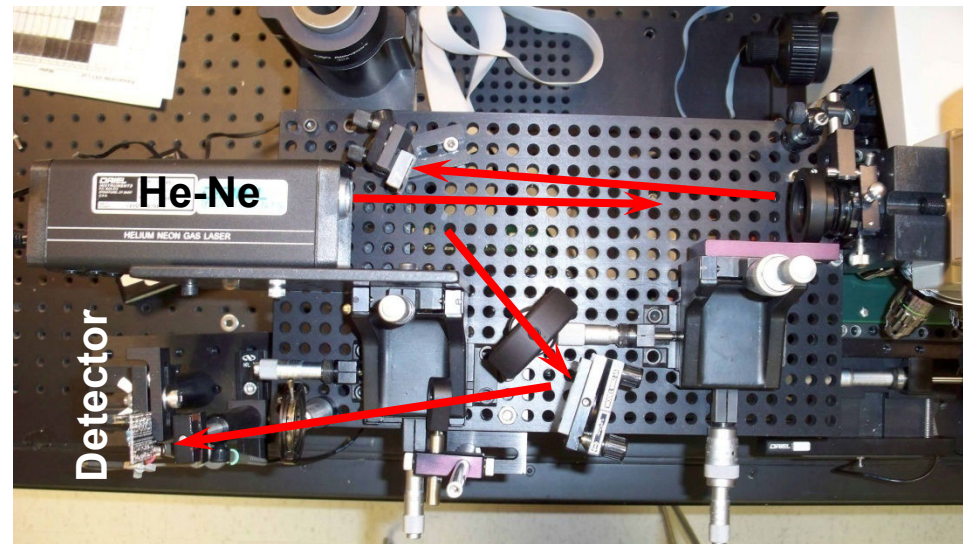
ITC Laser Microscopy System for GEMS Device Screening



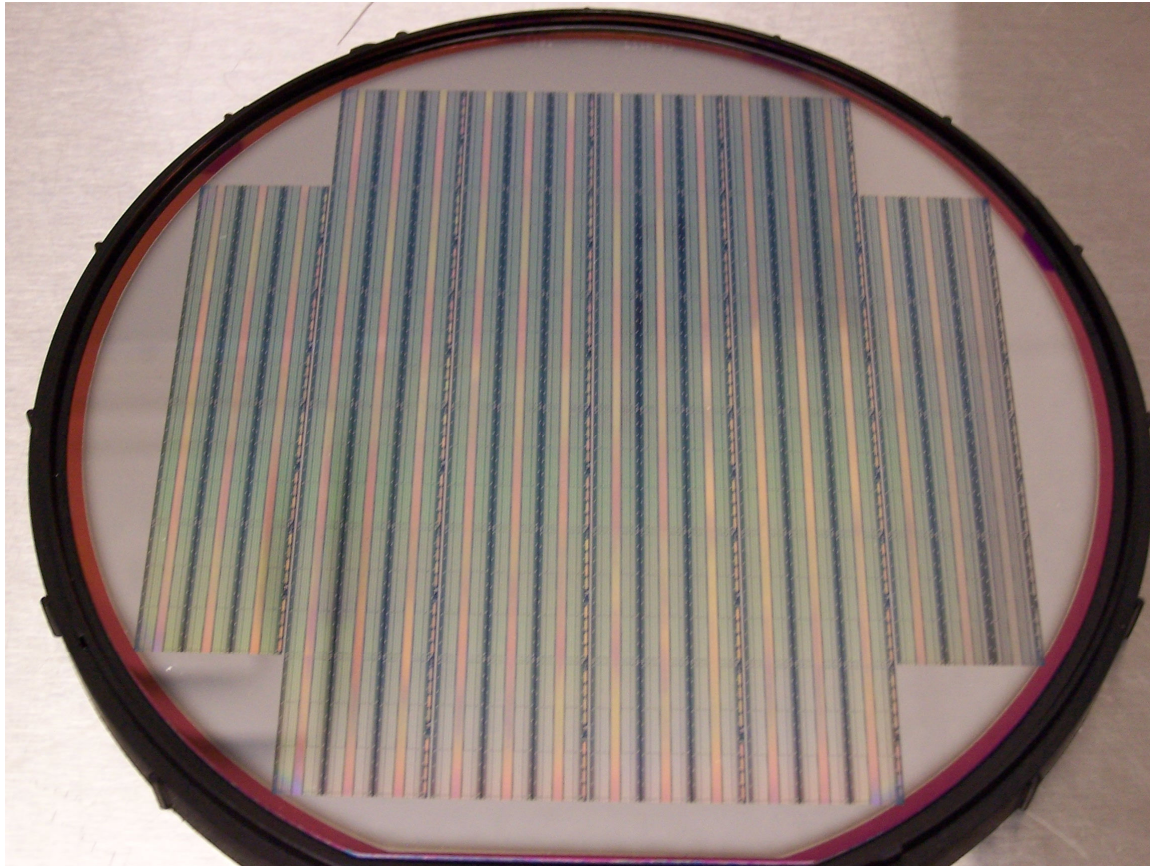
- Custom-modified high-quality microscope with laser probe beam for initial device screening
- System is configured to measure GEMS diffracted orders
- Provides feedback on device fabrication & packaging processes

Laser, Optics & Detector

GEMS Diffracted Orders Near Detector



GEMS Wafer from ITC



Thank You !

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References

- 1) M. W. Kowarz, J. C. Brazas and J. G. Phalen, "Conformal Grating Electromechanical Systems (GEMS) for High-Speed Digital Light Modulation," IEEE 15th International MEMS Conference Digest, pgs. 568-573 (2002).
- 2) J. D. Newman, M. W. Kowarz, J. G. Phalen, P. P. Lee and A. D. Cropper, "MEMS Programmable Spectral Imaging System for Remote Sensing," Spaceborne Sensors III, SPIE Proc. Vol. 6220, pgs. 53-61 (2006).
- 3) M. W. Kowarz, J. G. Phalen and C. J. Johnson, "Line-Scanned Laser Display Architectures Based on GEMS Technology: From Three-Lens Three-Chip Systems to Low-Cost Optically Efficient Trilinear Systems," SID Symposium Digest, Vol. 37, pgs. 1908-1911 (2006).
- 4) J. Agostinelli, M. W. Kowarz, D. Stauffer, T. Madden, and J. G. Phalen, "GEMS: A Simple Light Modulator for High-Performance Laser Projection Display," ITE/SID 13th International Display Workshops (IDW'06), pgs. 1579-1582 (2006).